

Readout Electronic System for the CEPC Ref. Detector

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On behalf of the CEPC Elec-TDAQ study team



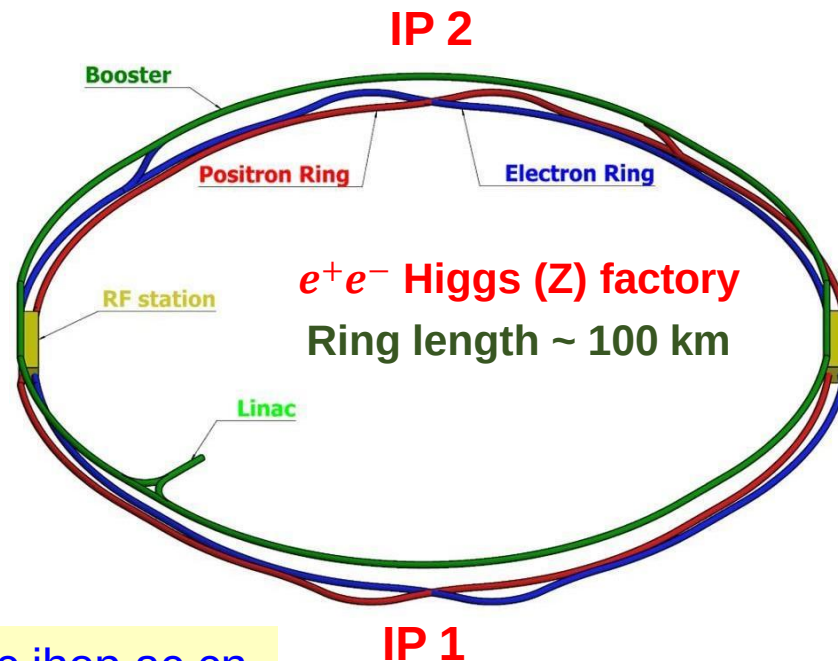
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Content

- **Introduction**
- **Requirements**
- **Technology options and our choices**
- **Global framework of the electronics system**
- **Detailed design for common electronics & new FEE ASIC**
- **Research team and working plan**
- **Summary**

The Circular Electron Positron Collider

- ❑ The CEPC was proposed in 2012 right after the Higgs discovery. It aims to start operation in 2030s, as an e^+e^- Higgs / Z factory.
- ❑ To produce Higgs / W / Z / top for high precision Higgs, EW measurements, studies of flavor physics & QCD, and probes of physics BSM.
- ❑ It is possible to upgrade to a pp collider (SppC) of $\sqrt{s} \sim 100$ TeV in the future.



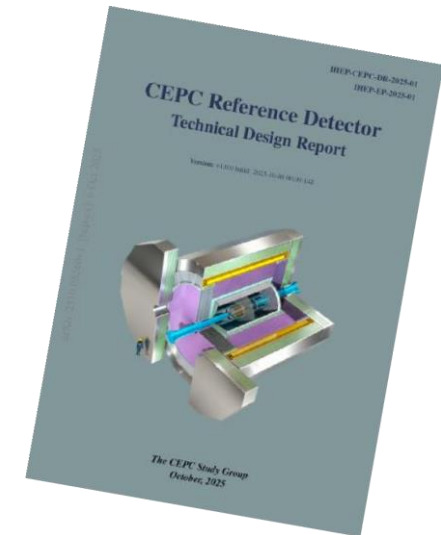
<http://cepc.ihep.ac.cn>



TDR of a Reference Detector

- ❑ In October 2025 the CEPC team released TDR of a reference detector
- ❑ This is to demonstrate the readiness and feasibility of the detector technologies. A detector that meets the requirements could be constructed and commissioned within a decade, and the scoped physics program could be fulfilled.

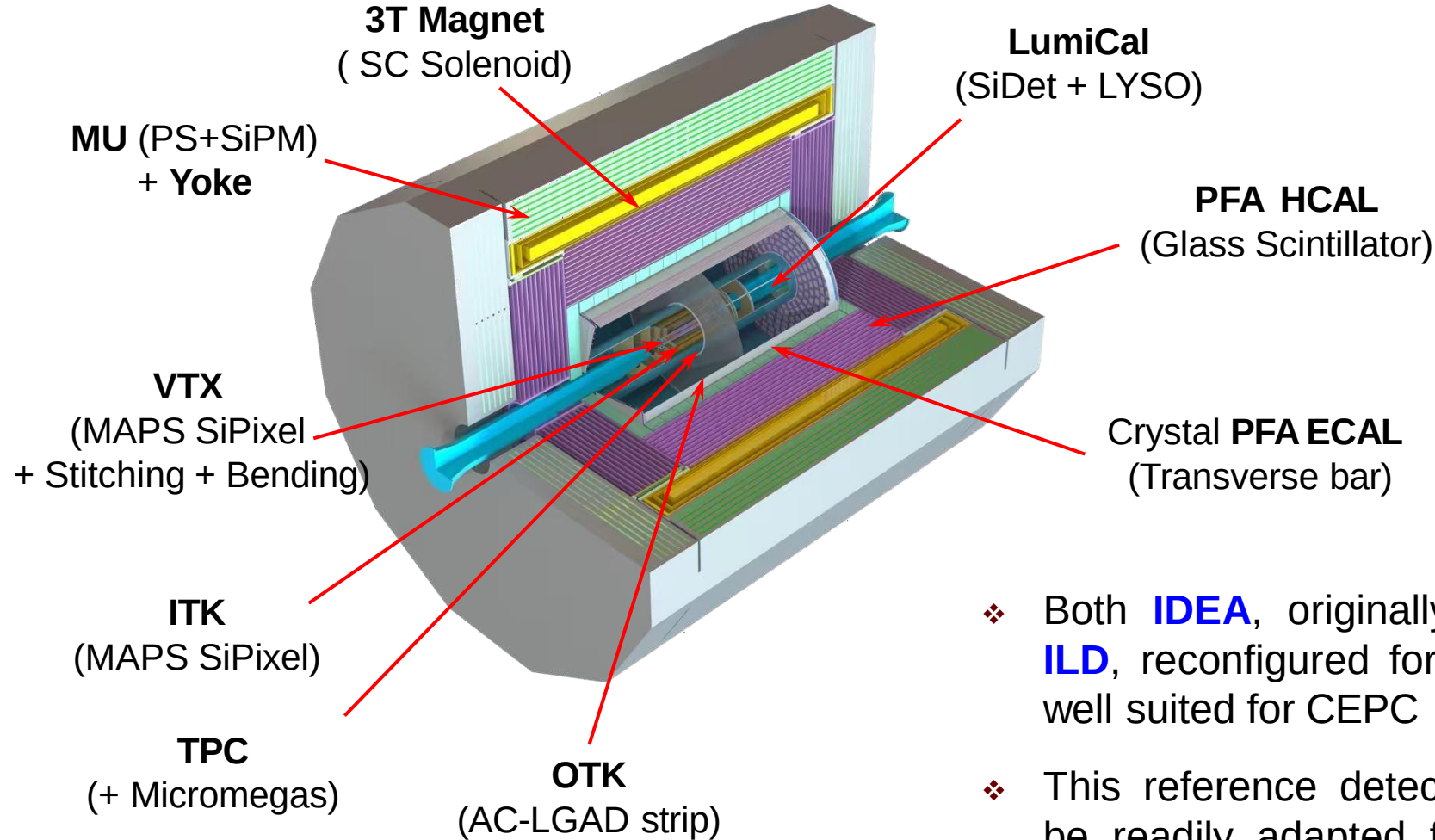
Baseline Scenario in TDR			
Operation mode	ZH	Z	W+W-
s [GeV]	240	91	~160
SR Power (MW)	30	12.1	30
L / IP [$\times 10^{34} \text{ cm}^{-2} \text{ s}^{-1}$]	5	26	16
Run Time [years]	15	4	1
$\int L dt$ [ab^{-1}], 1-IP	10	13	1.2
Event Yields	2.0×10^6	5.6×10^{11}	1.0×10^7



<https://doi.org/10.48550/arXiv.2510.05260>
1503 authors, 385 institutes, 47 countries

- ❑ After the baseline program being approved the international collaborations can propose and decide on the designs of the two final detectors. External contributions could bring back the initial physics program, maybe even the upgrade scenarios.

AGORA: Advanced Glass Optimized Research Apparatus



- ❖ Both **IDEA**, originally proposed for FCC-ee, and **ILD**, reconfigured for the circular e^+e^- collider, are well suited for CEPC
- ❖ This reference detector, designed for CEPC, can be readily adapted for use at other circular e^+e^- colliders, such as **FCC-ee**
- ❖ Official name determined: AGORA

Critical Input from Sub-Det & MDI

Background rate and data rate for the electronic system

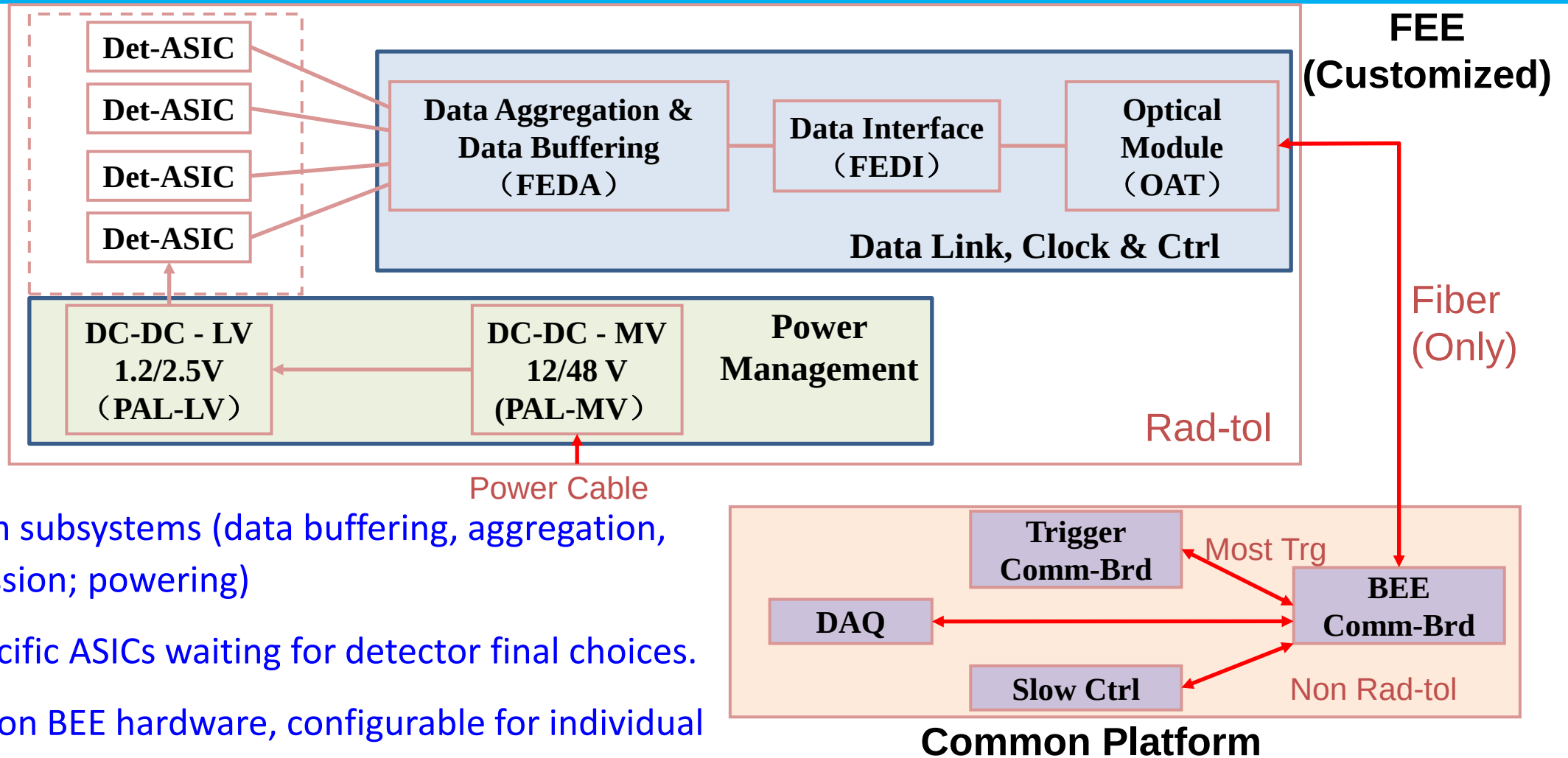
	VTX	ITK	OTK	TPC	ECAL	HCAL	Muon
Chn/ chip	512 × 1024	512 × 128	128	128	4-16 (common SiPM ASIC)		
Data Width	32 bit / hit	42 bit / hit	48 bit / hit	48 bit / hit	48 bit / hit		
Cluster size	3 pixel	1.5 pixel	2 strip	N/A	N/A		
Module Size/ Link	32.7 cm ² / stch chip	423.3 cm ² / / stave	365.7 cm ² / / stave	461 cm ² / module	856 chn w/ 1.5 cm bar	600 GS / Agg Brd	Agg Brd
Beam-induced background rate (MHz/cm ²)							
Higgs	6.4	3.0 × 10 ⁻³	1.9 × 10 ⁻³	2.4 × 10 ⁻³	6.2 × 10 ⁻²	2.4 × 10 ⁻⁴	1.4 × 10 ⁻⁶
LowZ	15.0	5.4 × 10 ⁻³	3.1 × 10 ⁻³	5.2 × 10 ⁻³	1.0 × 10 ⁻¹	2.4 × 10 ⁻⁴	9.2 × 10 ⁻⁷
Data rate per Link (Mbps)							
Higgs	2.00 × 10 ⁴	80.0	66.7	53.1	2.55 × 10 ³	6.91	< 10
LowZ	4.71 × 10 ⁴	144	109	115	4.11 × 10 ³	6.91	< 10

Time window and data rate for TDAQ system

	VTX	ITK	OTK	TPC	ECAL	HCAL	Muon	Total
Time windows (ns)	69	69	69	34000	69	1000	69	
50 MW Higgs mode Full Data (Gbps)	130	21.2	82.7	26.4	752	26.6	<1	1040
Data size / bunch (kB)	12.1	1.98	7.71	2.46	70.1	2.48	<0.1	96.9
Data size / event (kB)	12.1	1.98	7.71	303	70.1	9.92	<0.1	405
12.1 MW Z mode Full Data (Gbps)	307	37.8	139	57.1	1202	27.2	<1	1771
Data size / bunch (kB)	3.20	0.394	1.45	0.595	12.5	0.283	<0.1	18.4
Data size / event (kB)	6.40	0.788	2.90	293	25.0	4.53	<0.1	333

- Safety factor of 2 used for background rate estimation from MDI study
- Only Endcap data rate demonstrated for the highest requirements for the electronics
- Data rate includes: background rate * detector area * (possible) cluster size * data width
- MDI study is still in progressing, with more detailed distribution, radiation, and shielding

Global framework of the CEPC Elec system



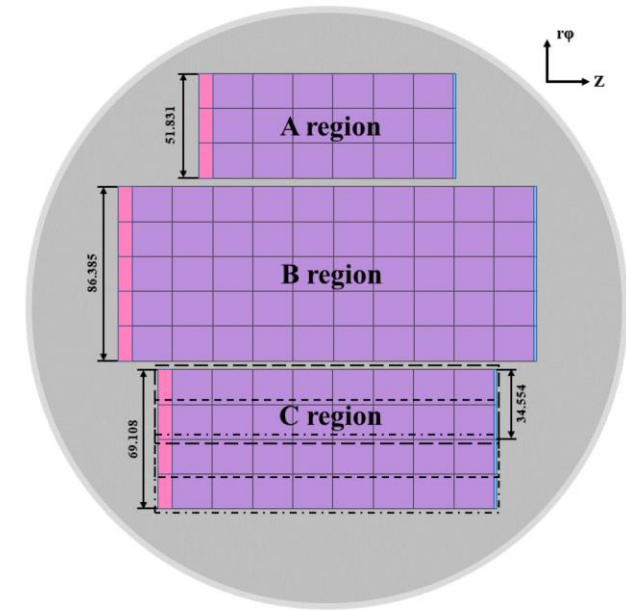
- Common subsystems (data buffering, aggregation, transmission; powering)
- Det. specific ASICs waiting for detector final choices.
- A common BEE hardware, configurable for individual subsystems.
- TDAQ interface is (probably) only on BEE

Key Electronics Components

- FEE ASICs for sub-detectors
- Common Data Link
- Common Powering
- Common Backend Electronics
- Alternative Scheme based on Wireless Communication

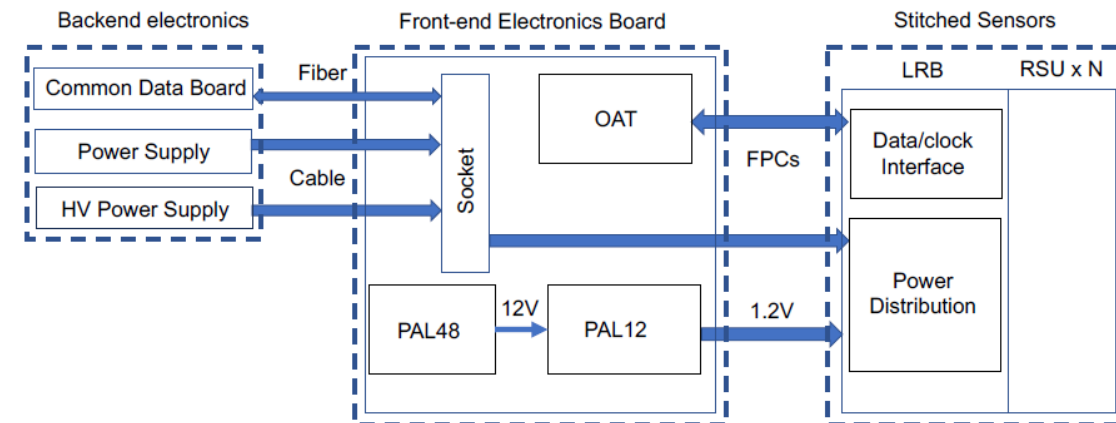
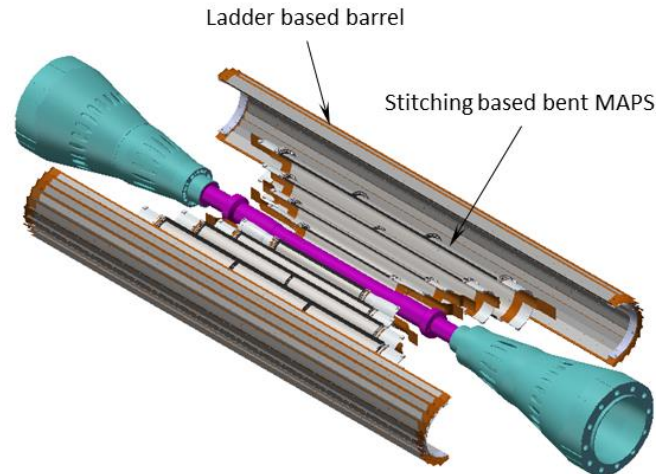
Vertex Detector Baseline layout

- Baseline : 4 single layer of bent MAPS + 1 double layer ladders
 - Alternative option: 3 double layer ladders
- Inner layer: Use single bent MAPS for Inner layer ($\sim 0.15\text{m}^2$)
 - Low material budget 0.06% X_0 per layer
 - Different rotation angle in each layer to reduce dead area
- Outer layer: Double layer Ladder ($\sim 0.28\%$ X_0 per layer)



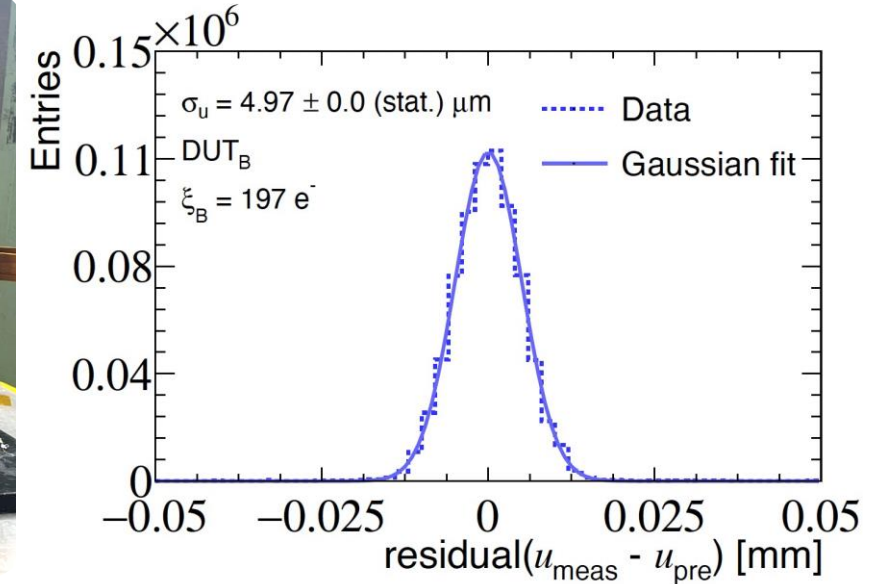
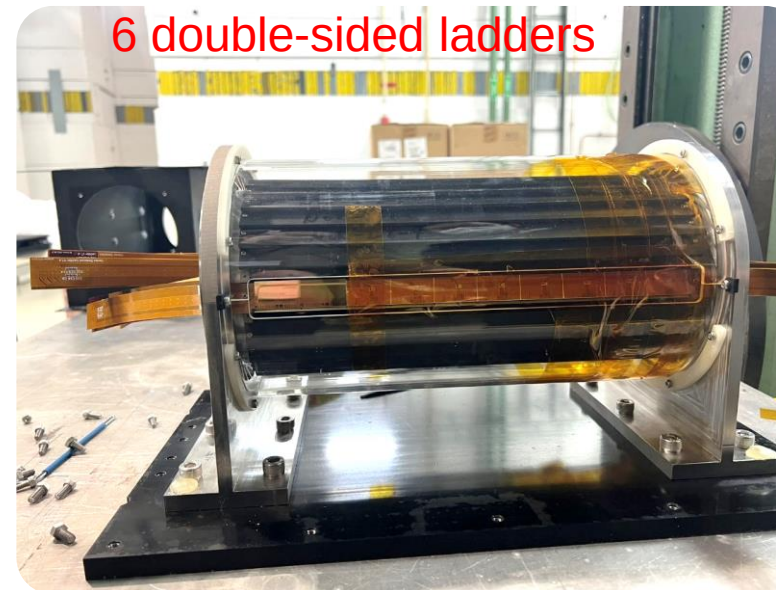
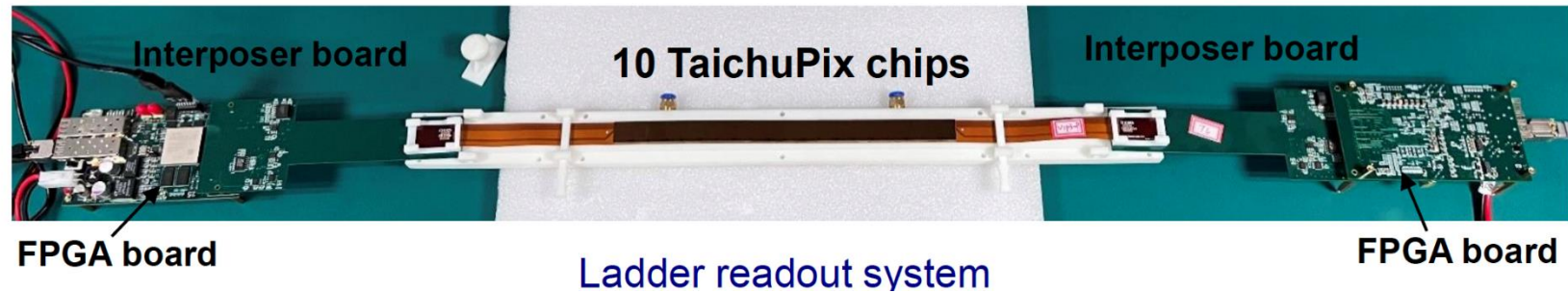
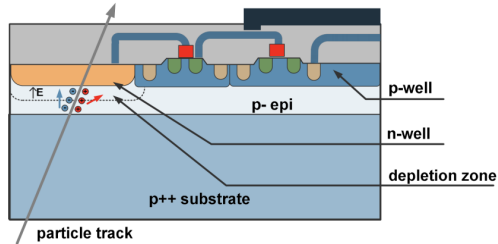
Long barrel layout (no endcap disk)
to cover $\cos \theta \leq 0.991$

CVTX/ PVTX X	radius mm	length mm
CVTX 1	11.1	161.4
CVTX 2	16.6	242.2
CVTX 3	22.1	323.0
CVTX 4	27.6	403.8
PVTX 5	39.5	682.0
PVTX 6	47.9	682.0



R&D effort: vertex detector prototype

Monolithic Pixels



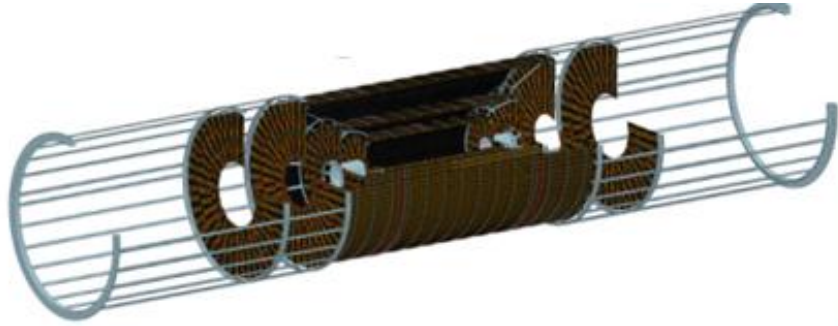
TaichuPix-based prototype detector tested at DESY in April 2023

Spatial resolution ~ 4.9 μm

See Wei WEI's presentation in TWEPP2023:

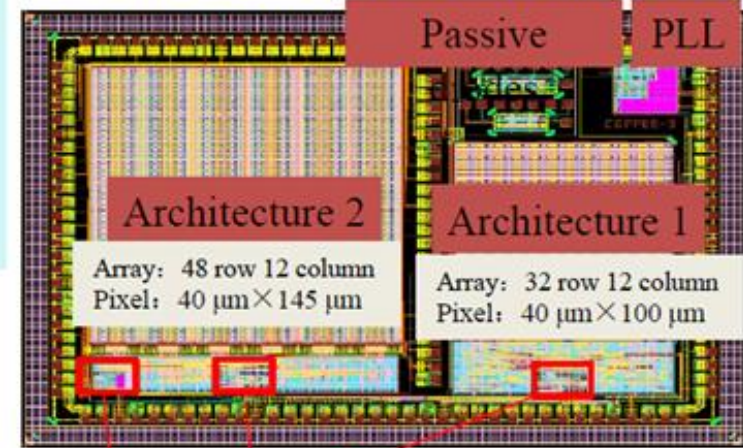
<https://indico.cern.ch/event/1255624/contributions/5443785/>

Inner Tracker with HV-CMOS Pixels



- Three barrel and four endcap layers ($\sim 20 \text{ m}^2$).
- HV-CMOS sensor COFFEE2 has verified the sensor process and in-pixel analog front-end.
- The latest COFFEE3 sensor, submitted for tape-out in Jan and received in May 2025, is currently undergoing testing.

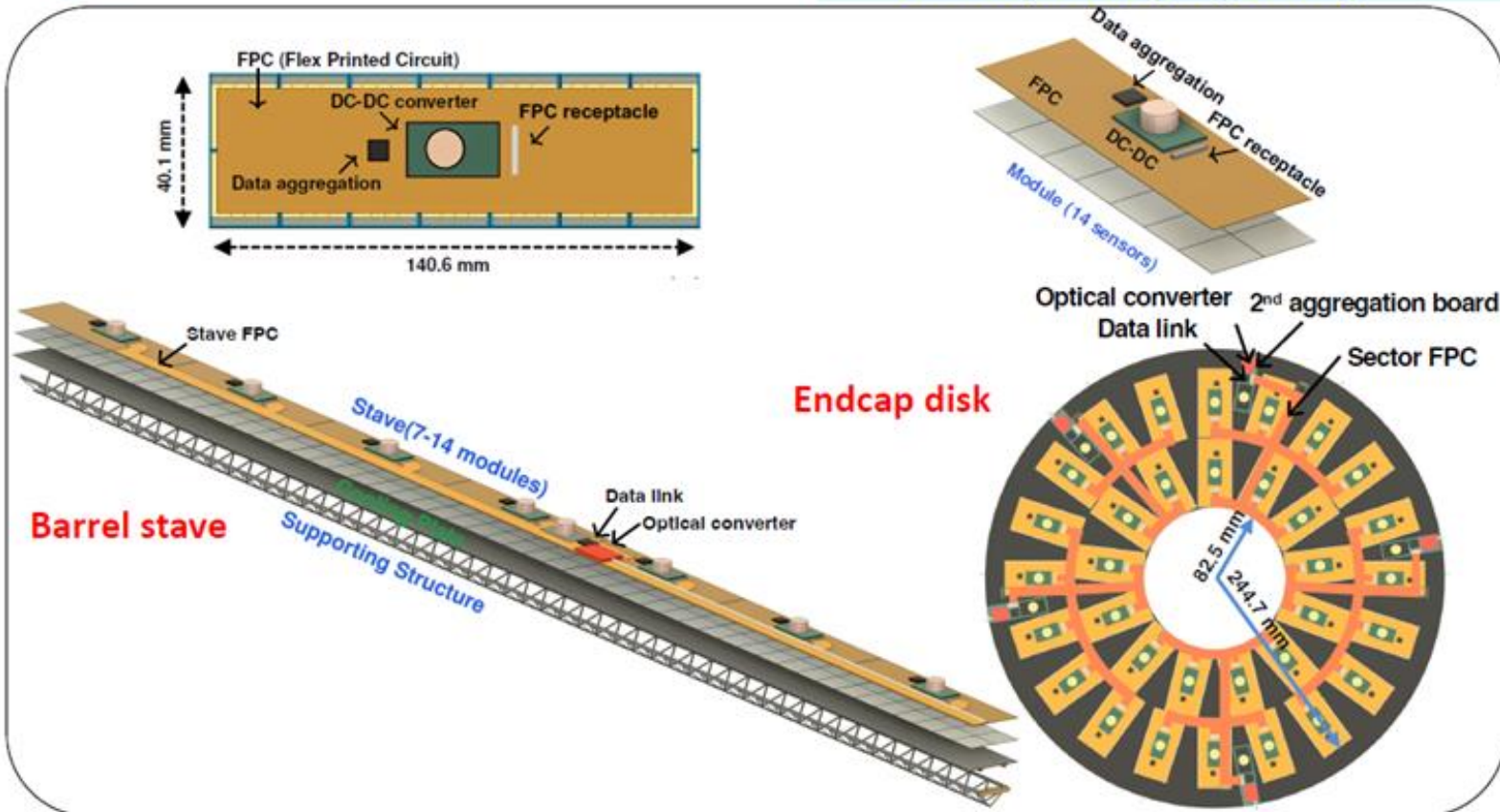
HV-CMOS sensor prototype (COFFEE3)



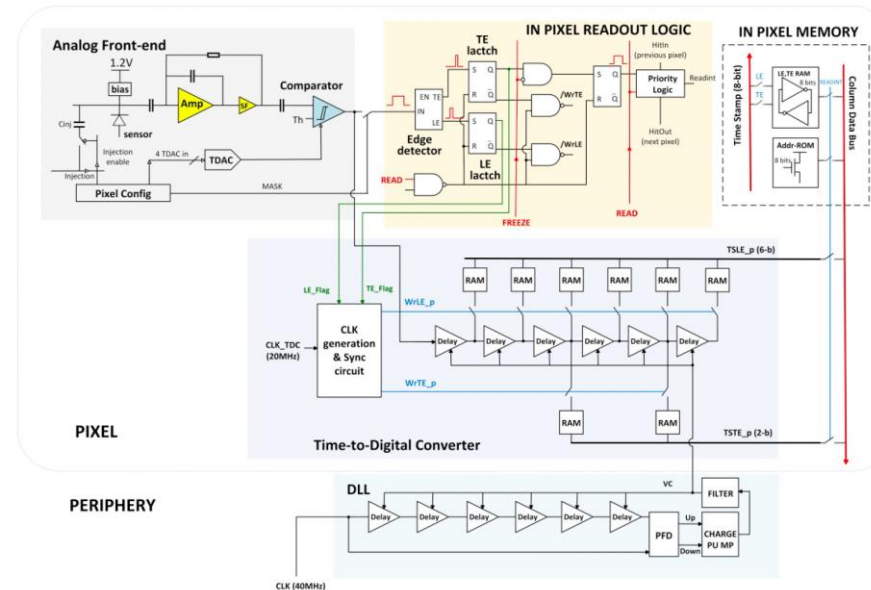
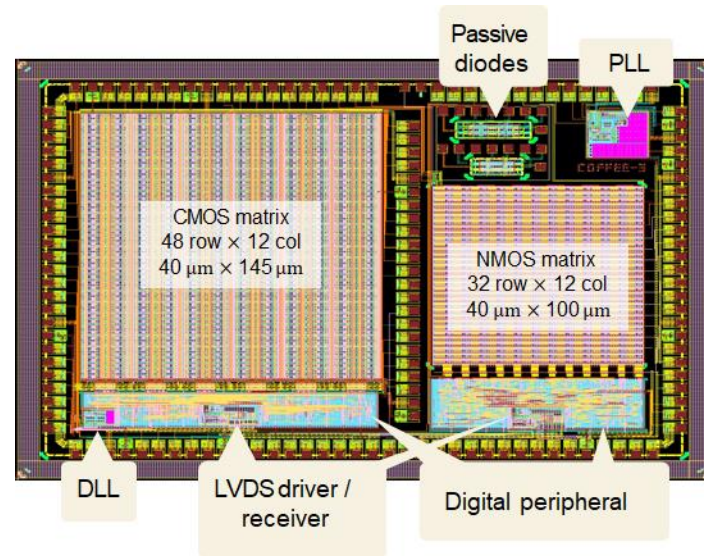
DLL LVDS driver/receiver

HV-CMOS sensor specification for ITK

Sensor size	2 cm $\times$ 2 cm
Sensor thickness	150 μm
Array size	512 $\times$ 128
Pixel size	34 μm $\times$ 150 μm
Spatial resolution	8 μm $\times$ 40 μm
Timing resolution	3-5 ns
Power	200 mW/cm ²
Process node	55 nm

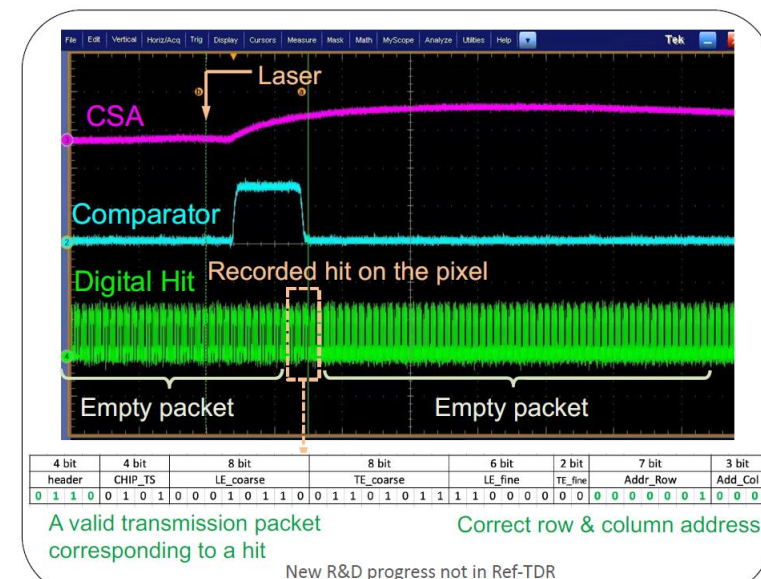
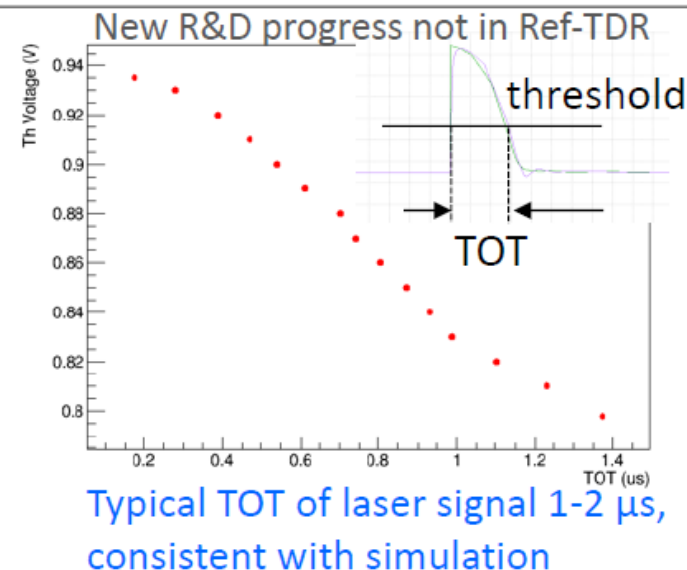
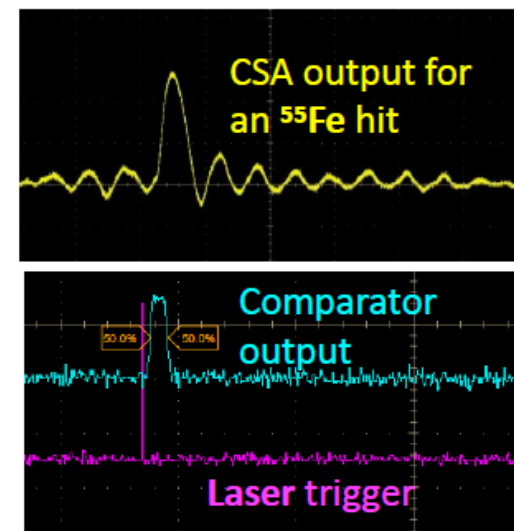


R&D Progress on HV-CMOS Pixel Sensor COFFEE



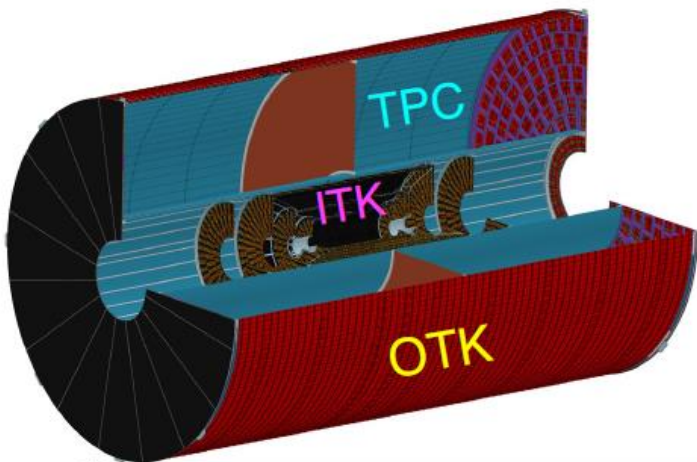
■ COFFEE3 chip designed on 55nm HVCMOS

- ‘CMOS matrix’: digital TDC in pixel
- ‘NMOS matrix’: limited design flexibility yet no crosstalk using 3- well
- IP validations: PLL, DLL, LVDS driver/ receivers ...



New R&D progress not in Ref-TDR

Outer Tracker Based on AC-LGAD Sensor



AC-LGAD prototype (latest submitted)

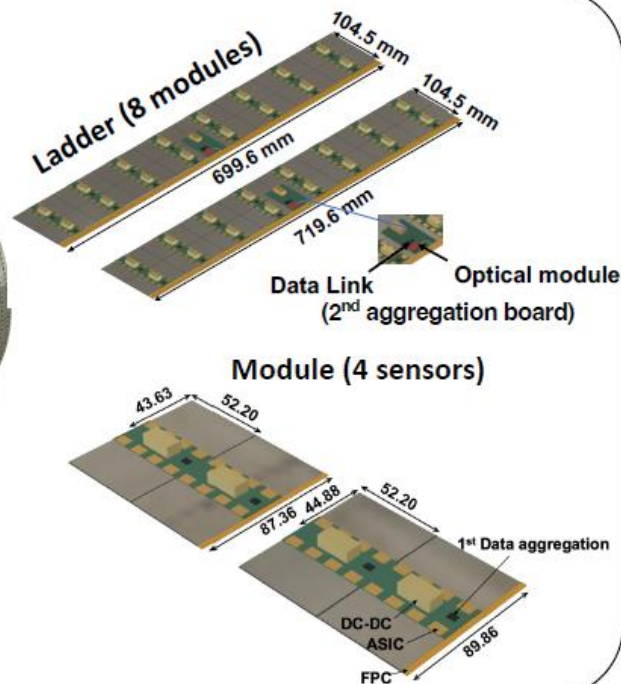
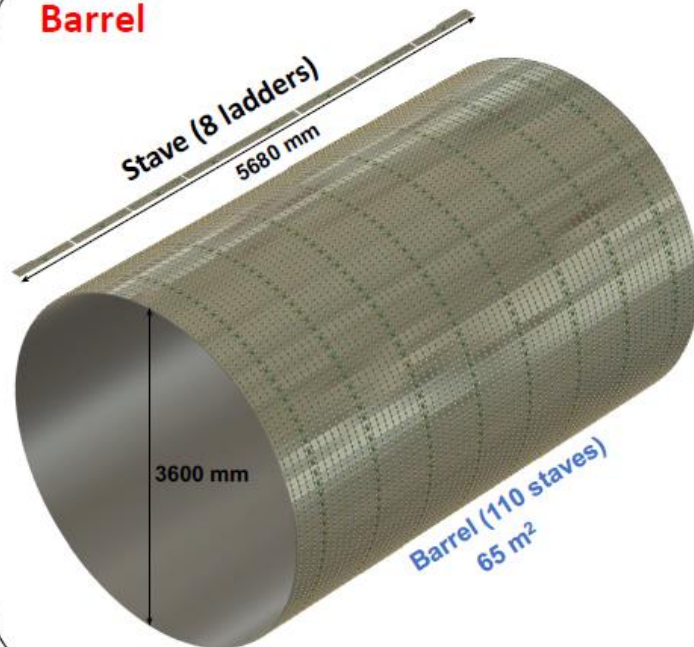


- One barrel layer and one endcap layer ($\sim 85 \text{ m}^2$).
- The latest LGAD sensor was submitted for tape-out in March and waiting for the return.

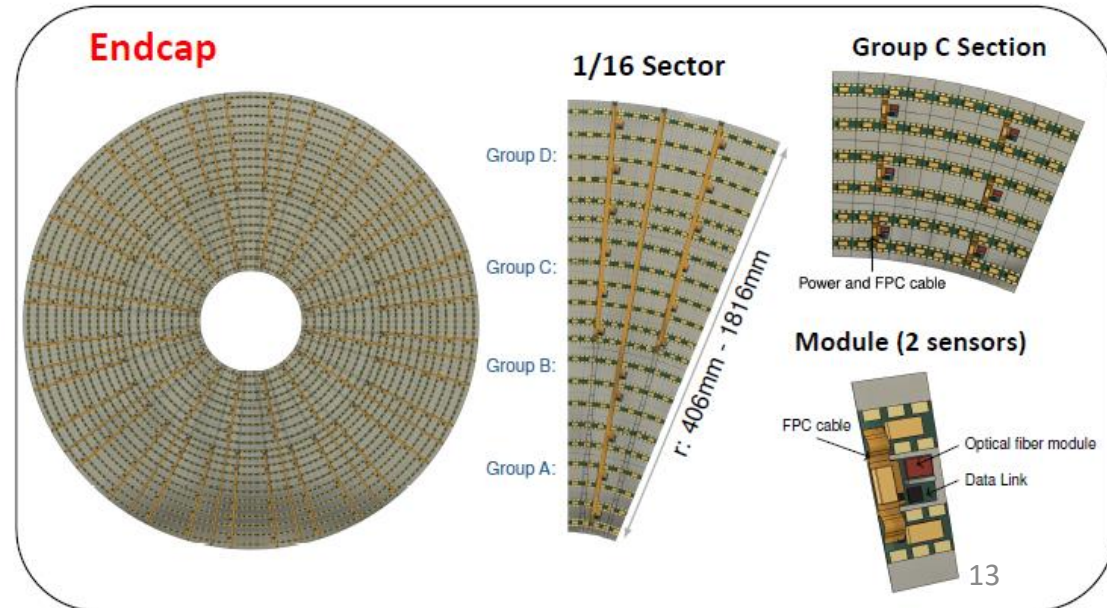
LGAD sensor specification for OTK

Sensor size	(3-4.5) cm $\times$ (3-5) cm
Strip pitch	$\sim 100 \mu\text{m}$
Spatial resolution	$10 \mu\text{m}$
Timing resolution	50 ps
Power	300 mW/cm ²

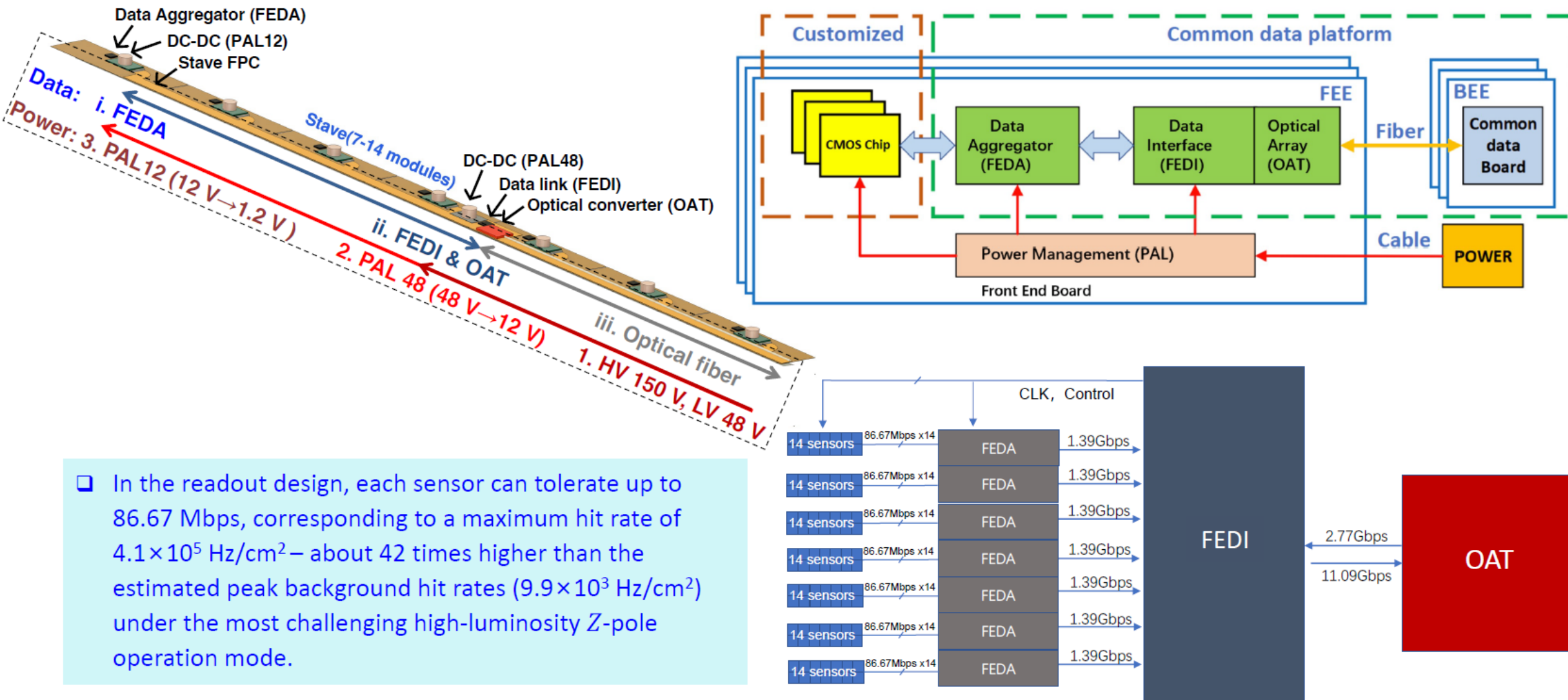
Barrel



Endcap



Readout Electronics framework for TRK



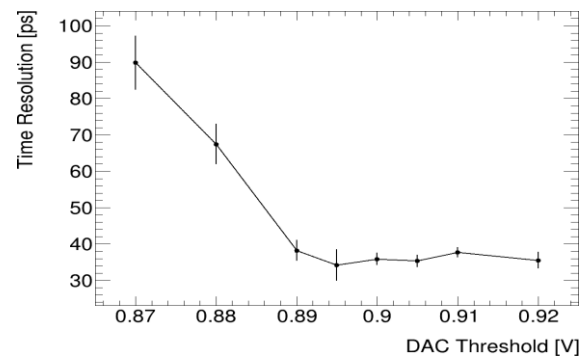
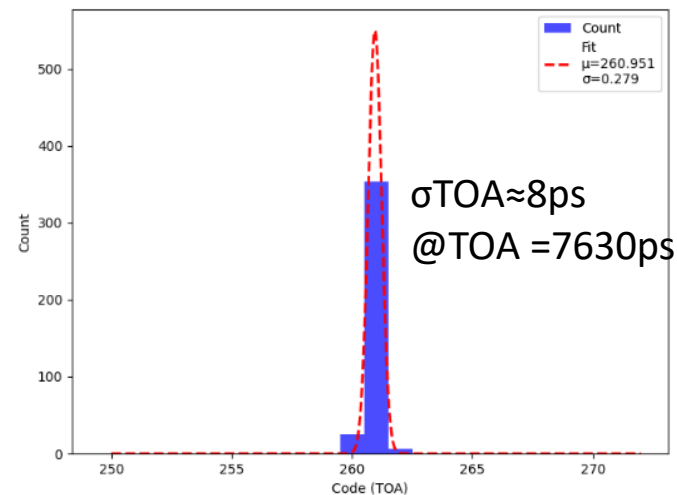
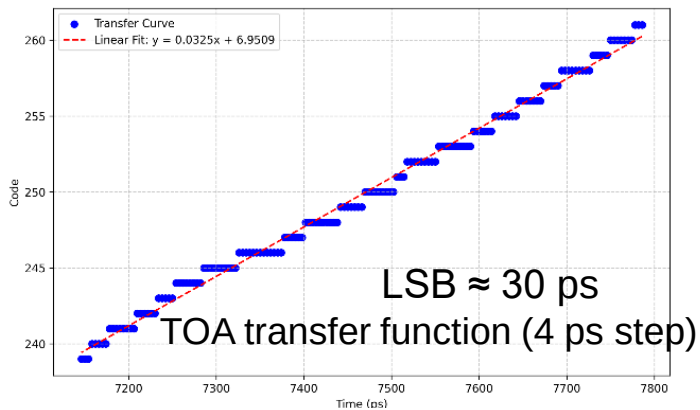
The FEDA, FEDI, OAT, and PAL chips are under development by the CEPC team.

Progress on AC-LGAD readout chip LATRIC

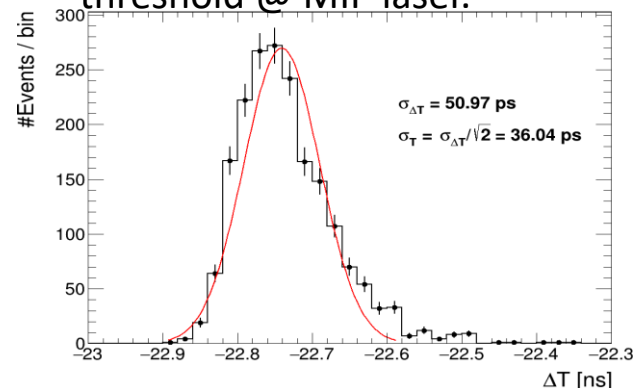
Two versions in 2025 Aug and Oct.

- It integrates Preamplifier, Discriminator, TDC, and Serializer.
- LATRIC-V0, with LSB of 29.8 ps, has been verified.

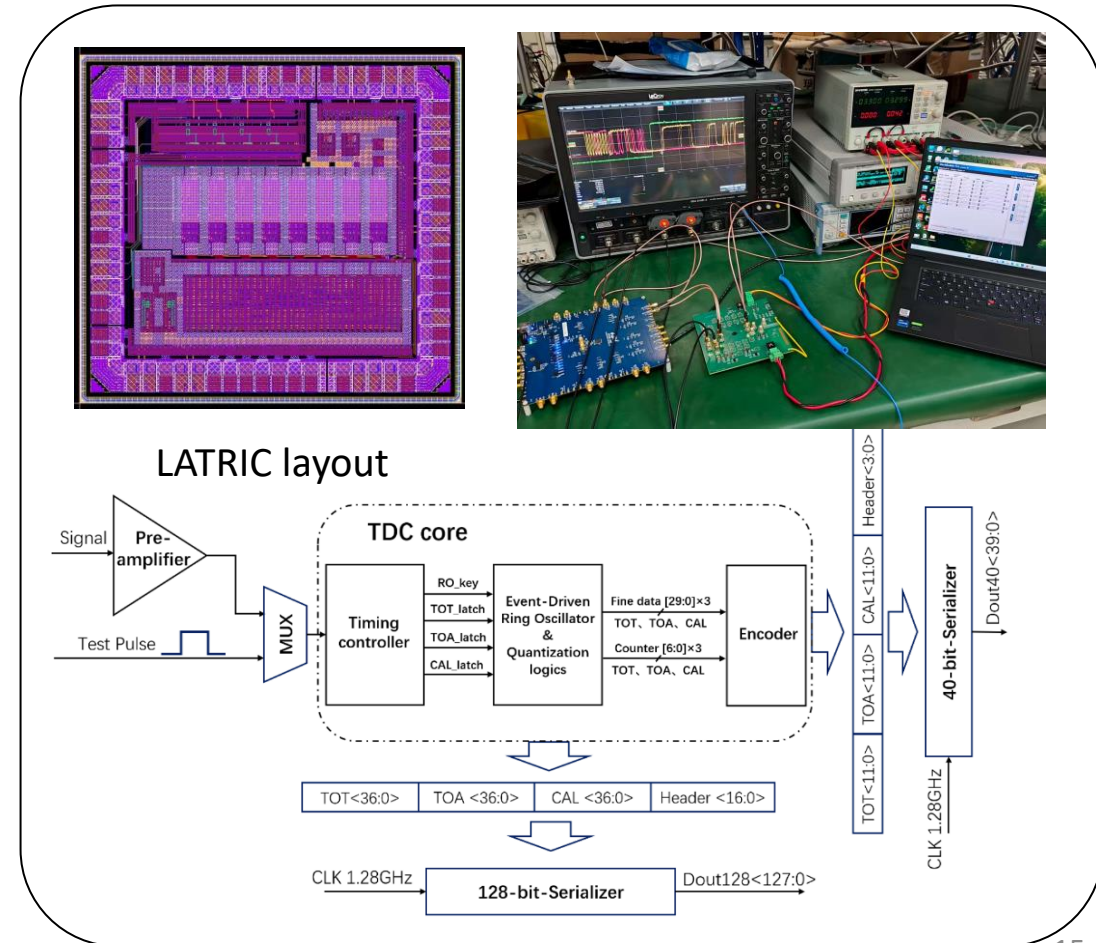
Tested with LGAD by wire bonding



The resolution decreases with threshold @ MIP laser.

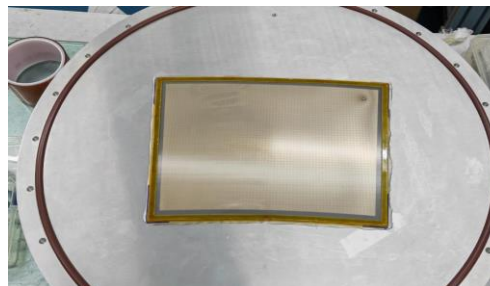
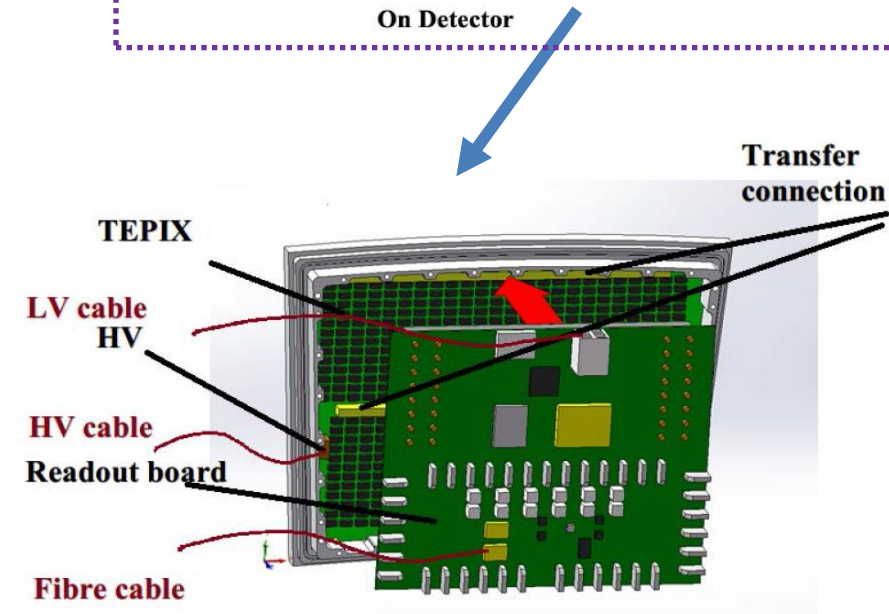
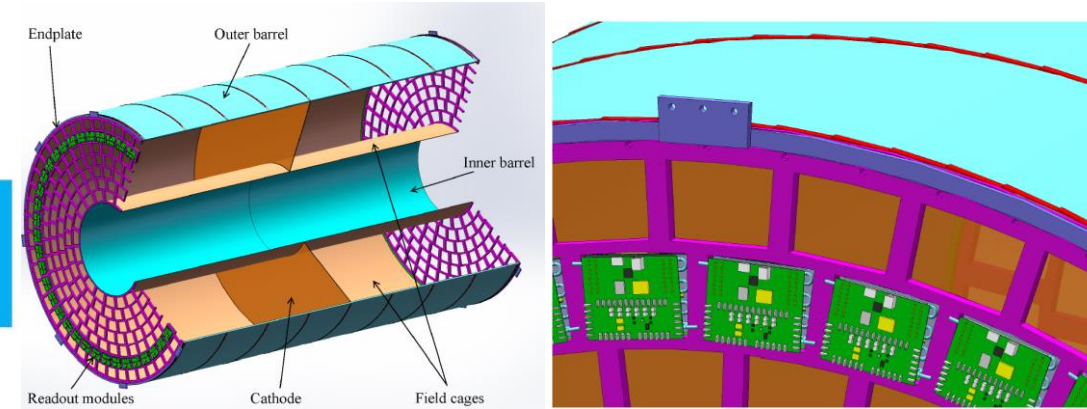
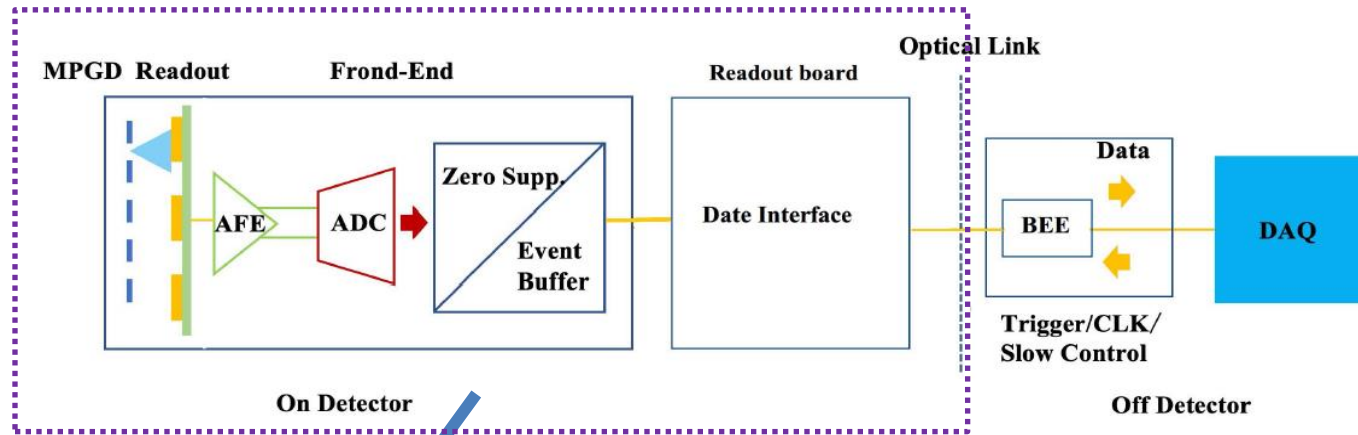


LATRIC + LGAD TOA coincidence
@ Laser intensity = MIP



TPC readout electronics

■ Electronics



■ On detector: readout modules

- Double-mesh Micromegas with high granularity readout ($500\mu\text{m} \times 500\mu\text{m}$ pad size) for electron multiplication and IBF suppression
- FEE board: a readout ASIC chip array. Interposer connection between pads and ASIC chips
- Readout board: data interface and data concentrator

■ Off detector:

- High-speed optical links
- Off-detector BEE
- Data Acquisition (DAQ) system

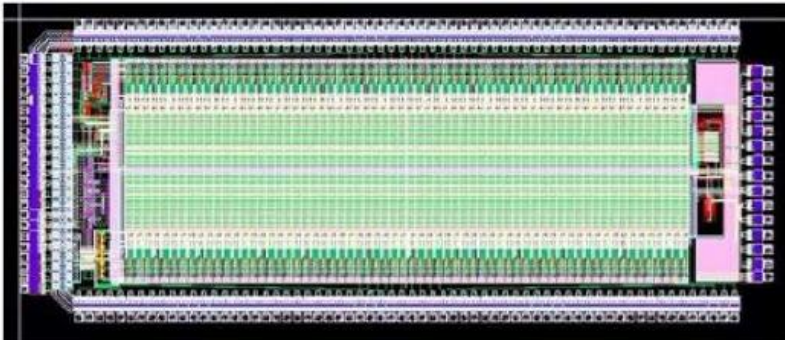
Detailed design of readout ASIC

■ Readout ASIC

- Low-power readout ASIC: TEPIX

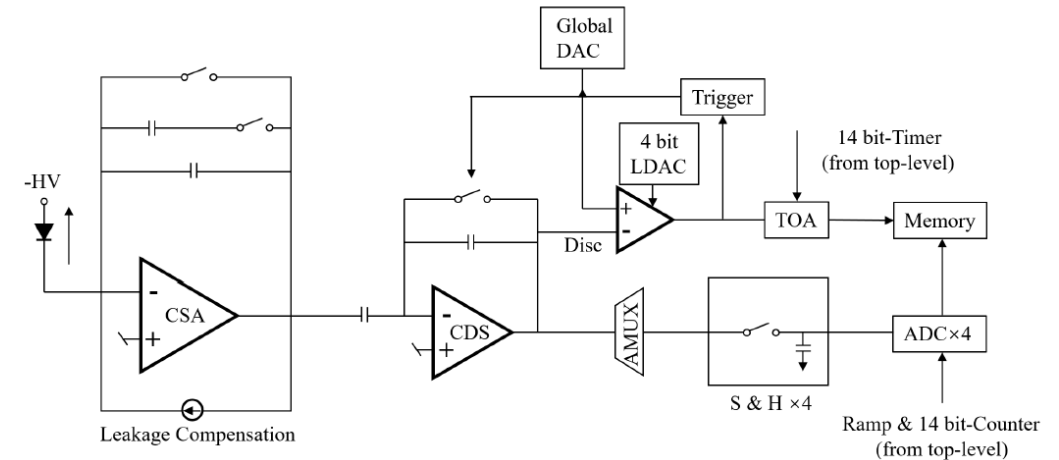
- Charge-sensitive preamplifier
- Correlated double sampling shaper
- 4-channel sample/hold circuits and 8-10 bit ADC
- 14 bit-timer (from top-level)

- Enabling precise charge (8-10 bit) and time-of-arrival (14-bit, 5 ns resolution) measurements



- TEPIX prototype

- 128 channels using 180 nm process
- Chip size: 2.2 mm × 5.6 mm

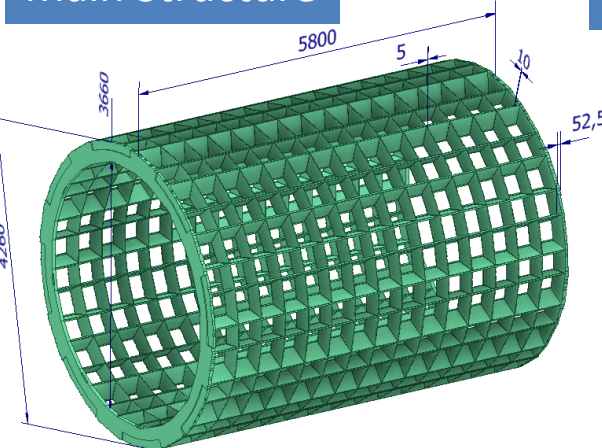


Total number of channels	30 Million per endplate
Pixel size	500 $\mu\text{m} \times 500 \mu\text{m}$
Equivalent Noise Charge (ENC)	100 e^-
Dynamic range	20 fC
Charge buffer dynamic range	8-10 bit
Event rate	12 kHz/cm ² max. in low-lumi. Z mode
Event size	64 bit
Readout bandwidth	<10 Gbps per module with compression
Power consumption	<100 mW/cm ²

- The pixel-array based chip will be designed, when the optimized pad-size of the TPC eventually determined

ECAL readout electronics

Main Structure



Module Integration

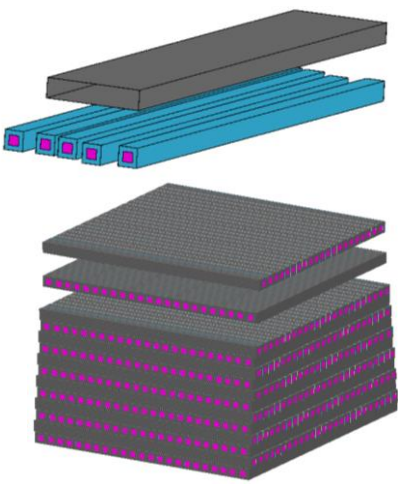
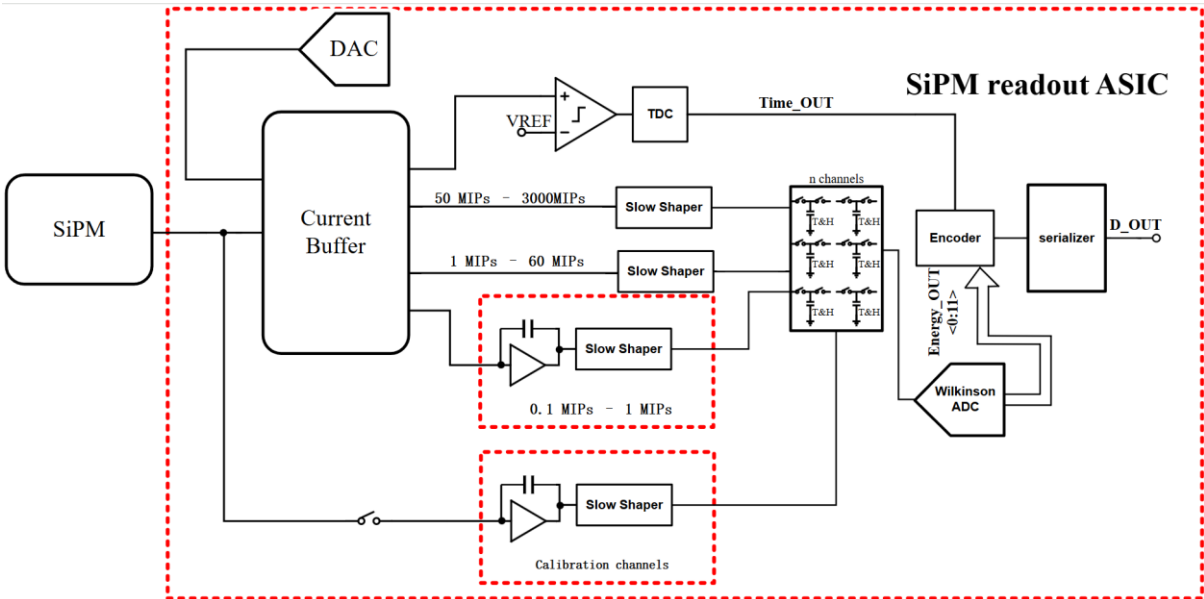
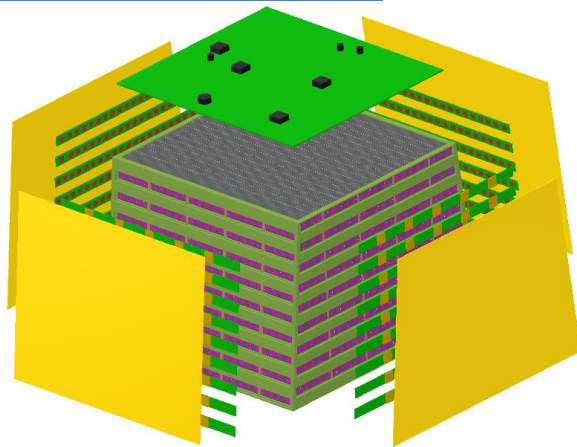


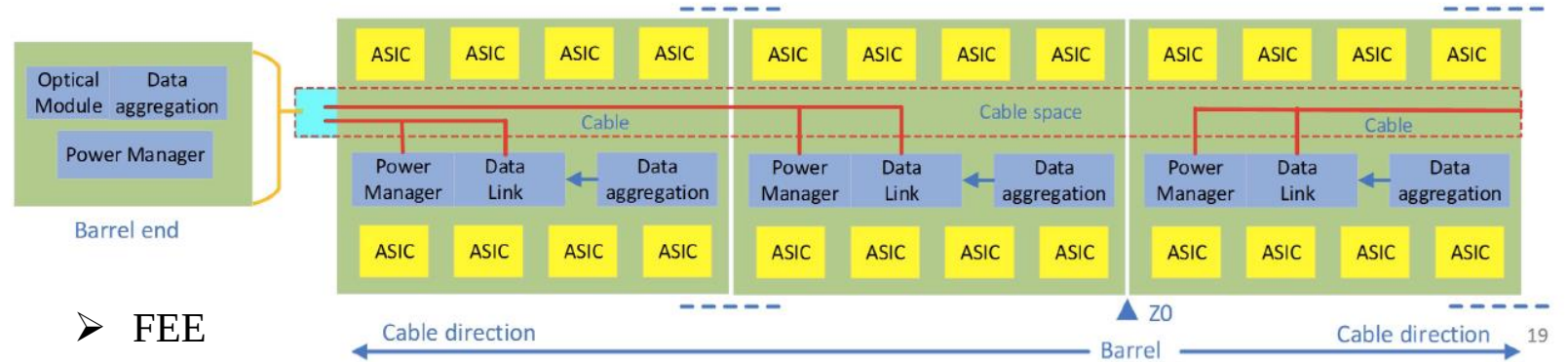
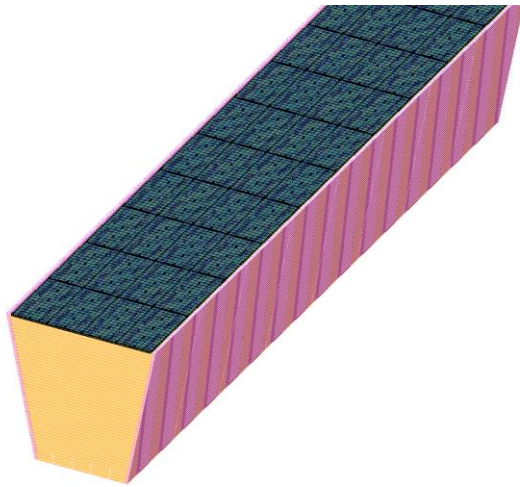
Table 11.2: Requirements of ECAL/HCAL SiPM for electronics

Parameters	Requirement of ECAL	Requirement of HCAL
Charge Dynamic Range	0.128 pC~3.84 nC (0.1~3000MIPs@100 p.e./MIP)	0.8~800pC (0.1~100MIPs@100 p.e./MIP)
Timing Measured Range	TBD from electronics	TBD from electronics
Charge Resolution	30% @ 0.1 MIP, 10% @ 1.0 MIP, 1% @ 100 MIPs	10% of 1.0 MIP, i.e. 10 p.e.
Timing Resolution	200 ps @ 1 MIP, 100 ps @ 12 MIPs	
Integral Non-linearity	Better than SiPM's	
SiPM Capacitance	≤ 50 pF	≤ 100 pF
SiPM Gain	8×10^4	$\geq 5 \times 10^5$
Average Event Rate/channel	13 kHz	Lower than ECAL's
Max Event Rate/channel	230kHz	Lower than ECAL's
Typical Signal Rising Edge	40ns	
Typical Signal Width	$\geq 1 \mu s$ (BGO decay time is 300ns)	$\geq 1 \mu s$ (Glass decay time is longer than 300ns)
Other Requirement	SiPM bias voltage fine tuning 0.5V	

Table 11.3: Specifications of the SIPAC ASIC

Characteristics	Value
Charge Dynamic Range	0.128 pC~3.84 nC
Charge resolution	30% @ 0.128pC, 10% @ 1.28pC, 1% @ 128pC 1% @ 100 MIPs
Time resolution(RMS)	200 ps @ 1.28pC, 100 ps @ 12.8pC
Detector Capacitance	≤ 100 pF
Max signal rate/channel	500 kHz/ch
ADC	10-bit
TDC resolution	8-bit
TDC bin width	100 ps
Power consumption	15mW/channel
Num. of channels	4

HCAL readout electronics



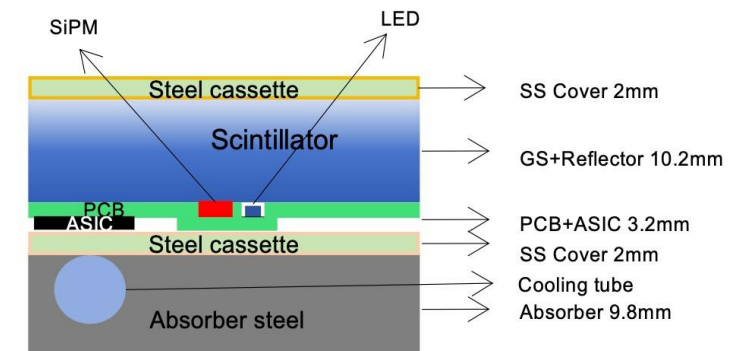
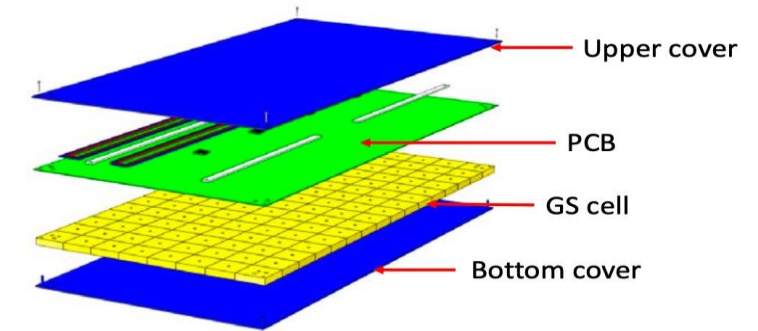
- **Front-End Electronics (FEE) readout boards in HCAL cell Box**

- Thickness: 3.2mm = PCB 1.2mm + ASIC Chip 2mm
- SiPMs, ASICs and Data Aggregation
- PCB dimensions: flexible in different positions

- **SiPM-readout ASIC: under development**

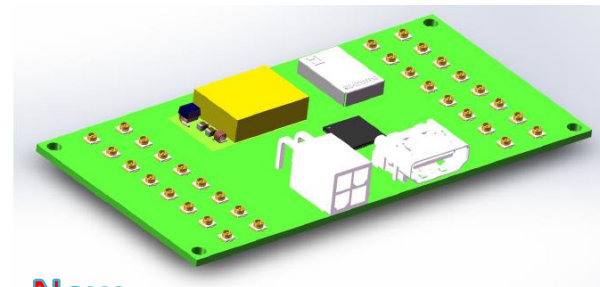
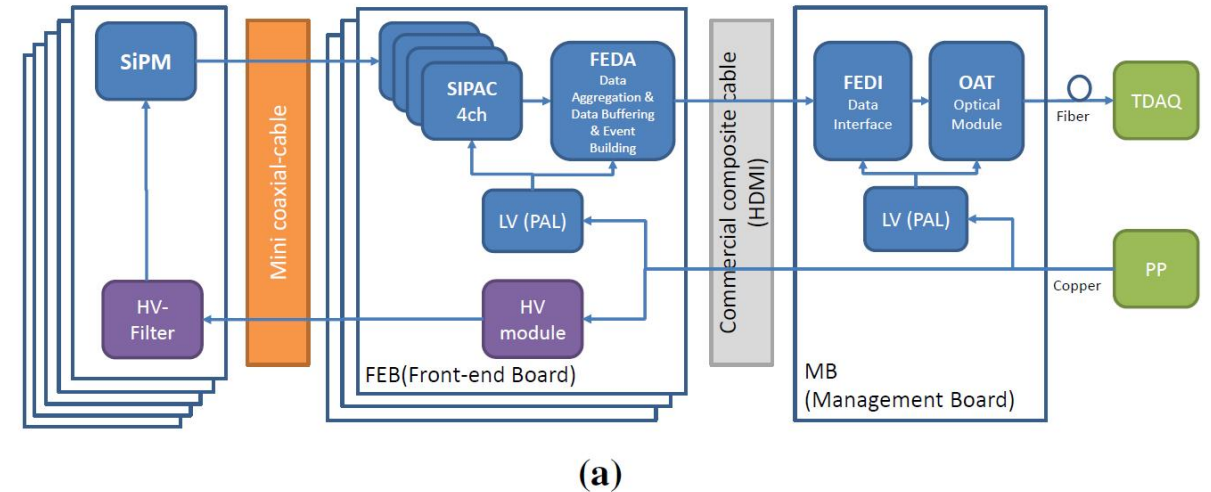
- Self-developed for CEPC calorimeter system
- Functionality: energy and time measurements
- Power consumption: target at 15mW/ch

- **Aggregation board at the end of barrel, cable connection**

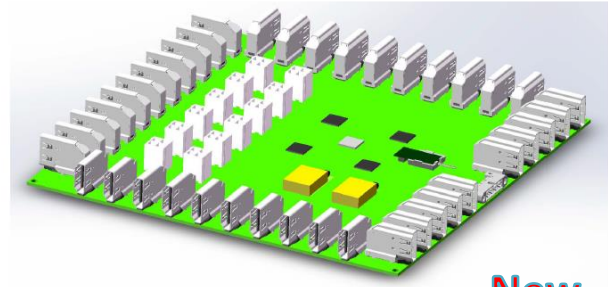


Muon readout electronics

- According to the R&D results and required performance: $N_{pe} > 200$, $\sigma_T < 0.5ns$
- Use the same chip designed for calorimeter, but customize the FEB based on ASIC according to the constraints in detector modules.
- Three stages for readout
 - SiPM tile: SiPM on PCB
 - FEB: Front-End Electronics Board, each having 32 chs, mini HV generator integrated.
 - MB: Management Board, central node for multiple functions.



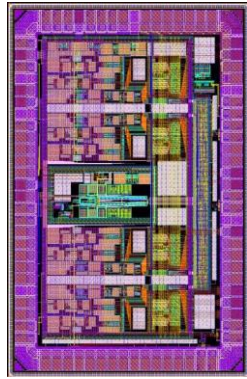
(b) FEB



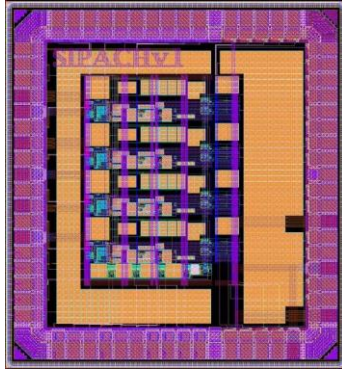
(c) MB

Fig. 9.3

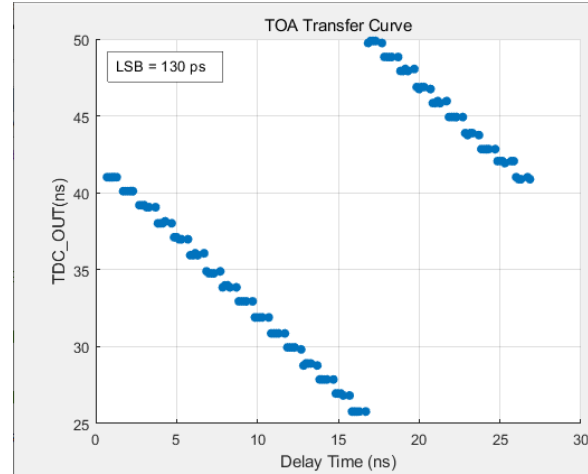
Progress on SiPM readout ASIC SIPAC



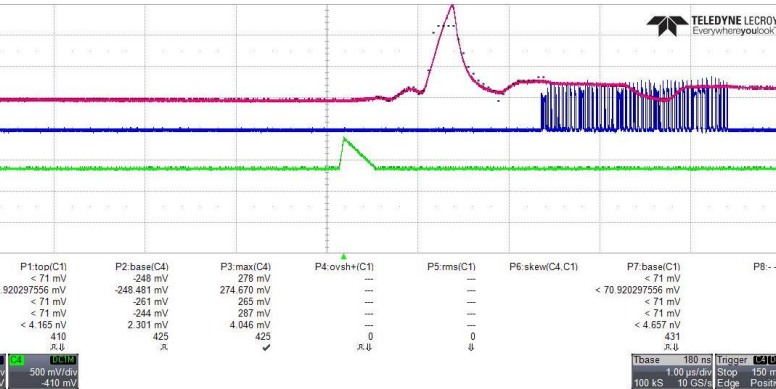
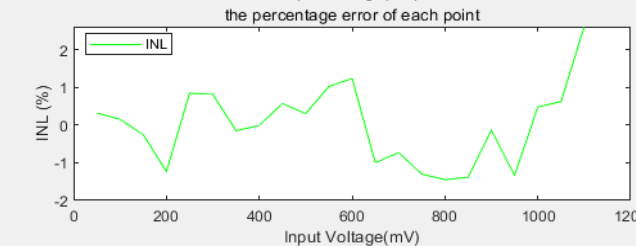
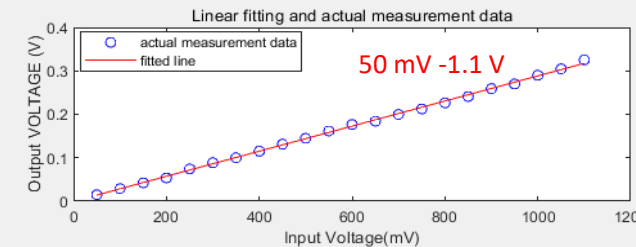
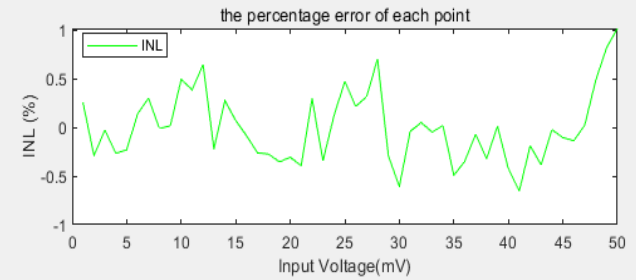
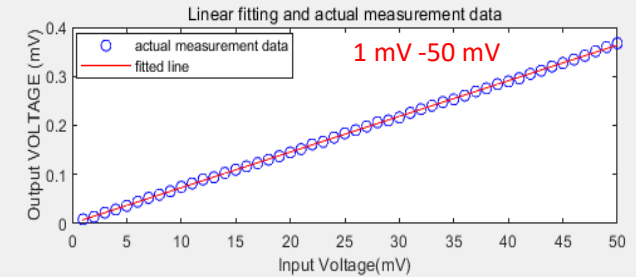
SIPAC-E



SIPAC-H



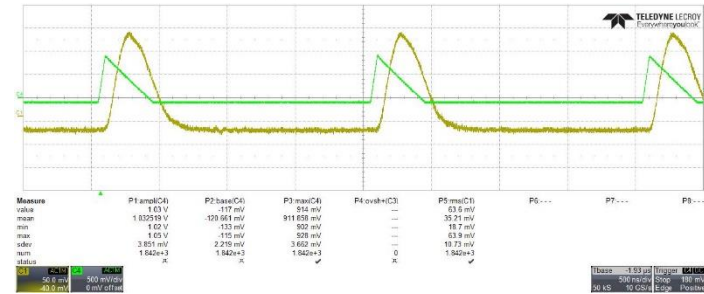
TDC tested transfer curve



ADC digitization functionality test

Dynamic range
of the high/low gain range²¹

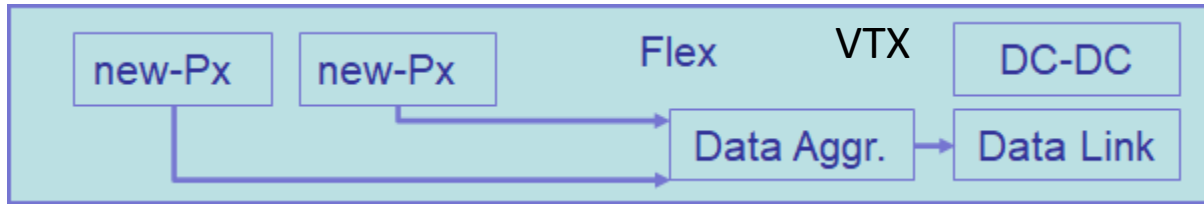
High gain output (yellow, 20mV small)



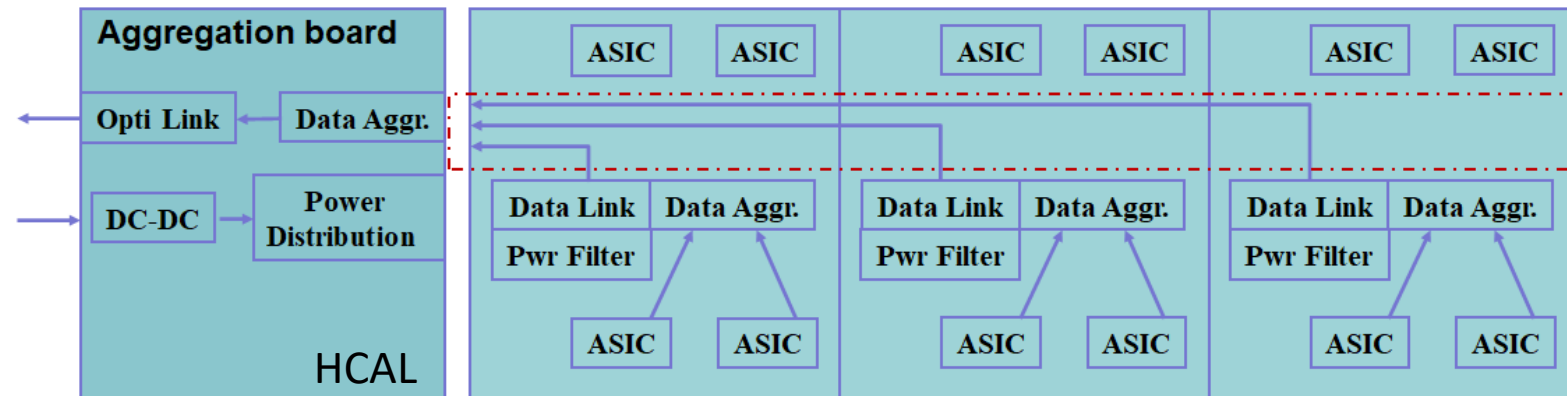
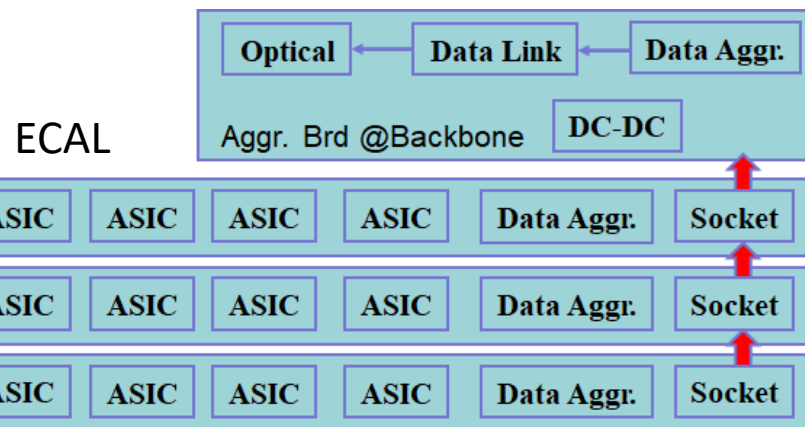
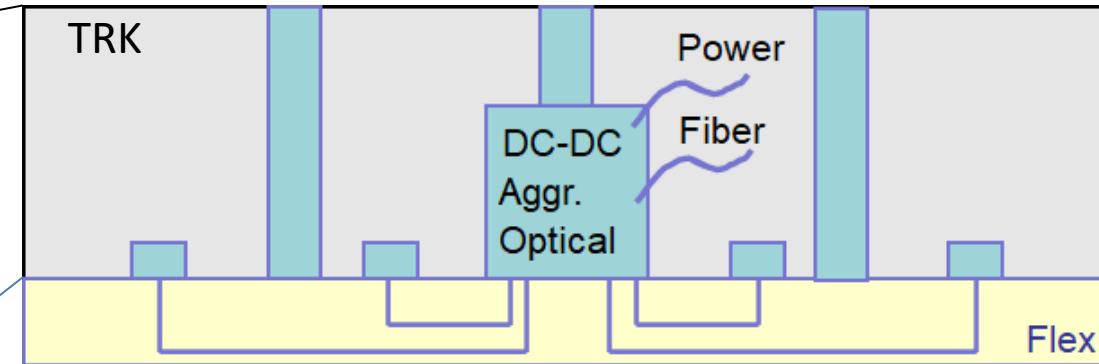
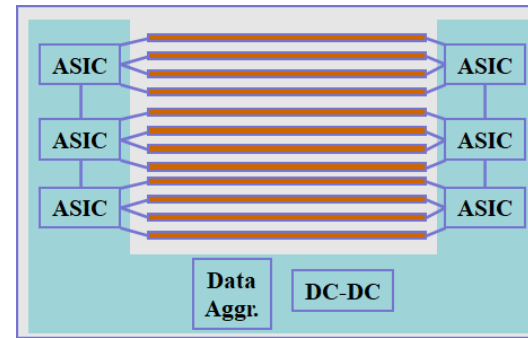
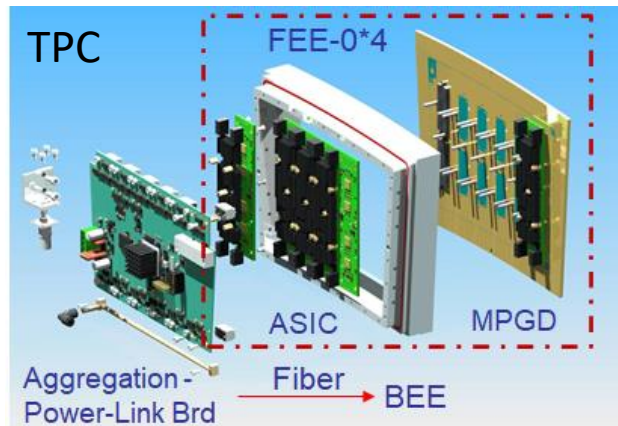
Low gain output (yellow, 200mV large)

■ Preliminary test results achieved, further test ongoing

An overview of the Sub-Det readout Elec.



- All sub-det readout electronics were proposed based on this unified framework, maximizing the possibility of common design usage.



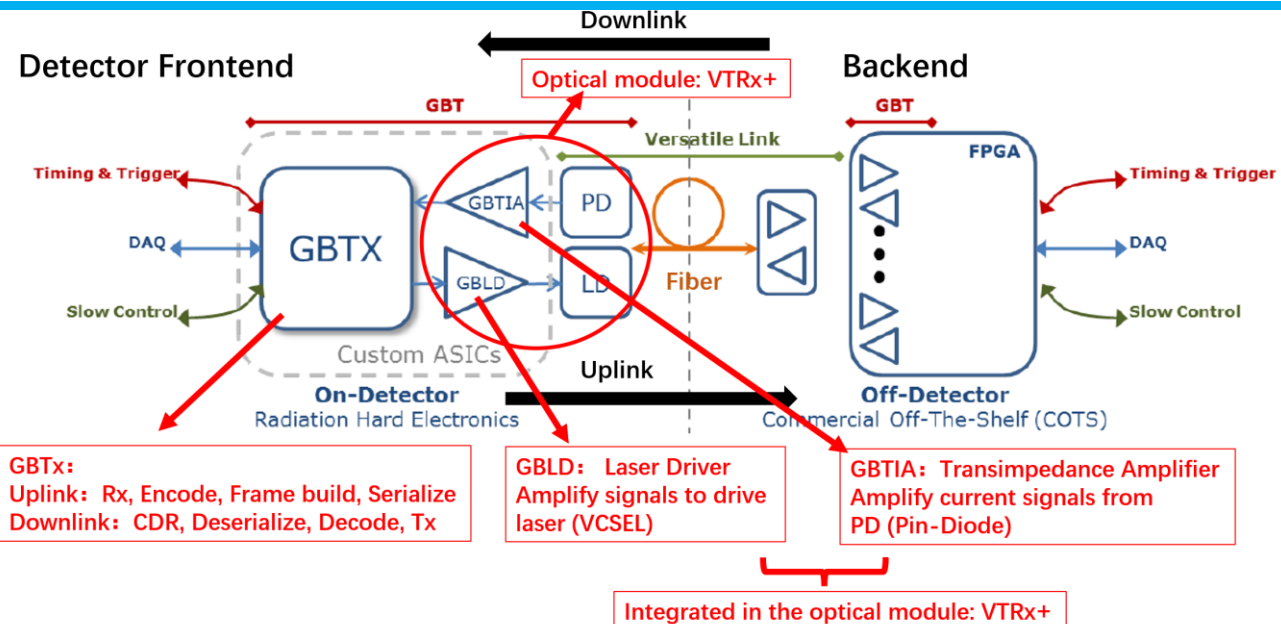
Technical Survey on Data Transmission System

- GBT Project:

- The lpGBT & VTRx chip series, developed by CERN, are widely used by LHC experiments, as a common project
- Core components:
 - GBTx: Bidirectional Serdes ASIC
 - GBLD: Laser driver
 - GBTIA: Transimpedance amplifier
 - Customized Optical Module
- However the base clock frequency of CEPC 43.3MHz is not compatible with lpGBT system

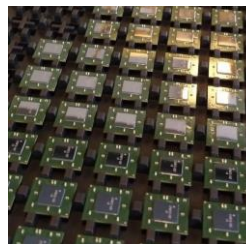
■ Our choice:

- Build a GBT-like universal bidirectional data transmission system
- Take the lpGBT as a reference, the protocol can be a minimum & necessary set for the readout, clocking & control

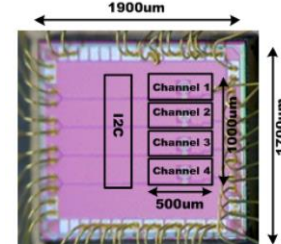


GBT Architecture Developed by CERN

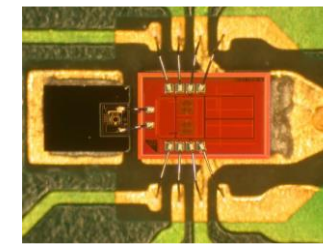
Ref. P. Moreira, The GBT Project, 2007



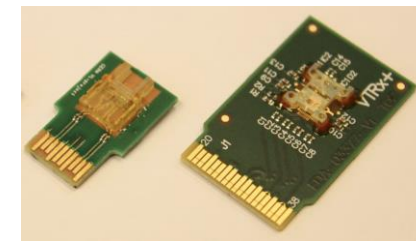
IpGBTx
Uplink: 10.24Gbps
Downlink: 2.56 Gbps



GBLD (LDQ10)
10.24 Gbps x 4ch



GBTIA
2.56 Gbps

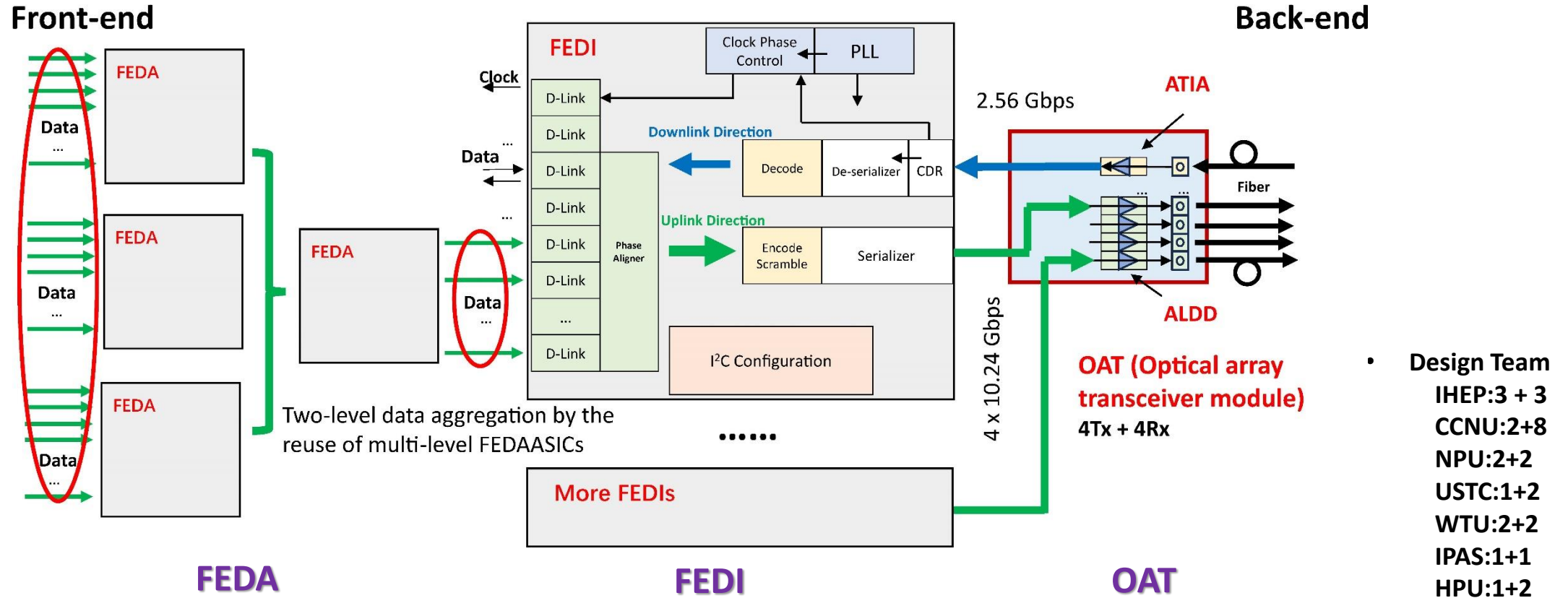


VTRx+
4Tx + 1Rx
Array Optical Module

GBT Series ASICs and optical module

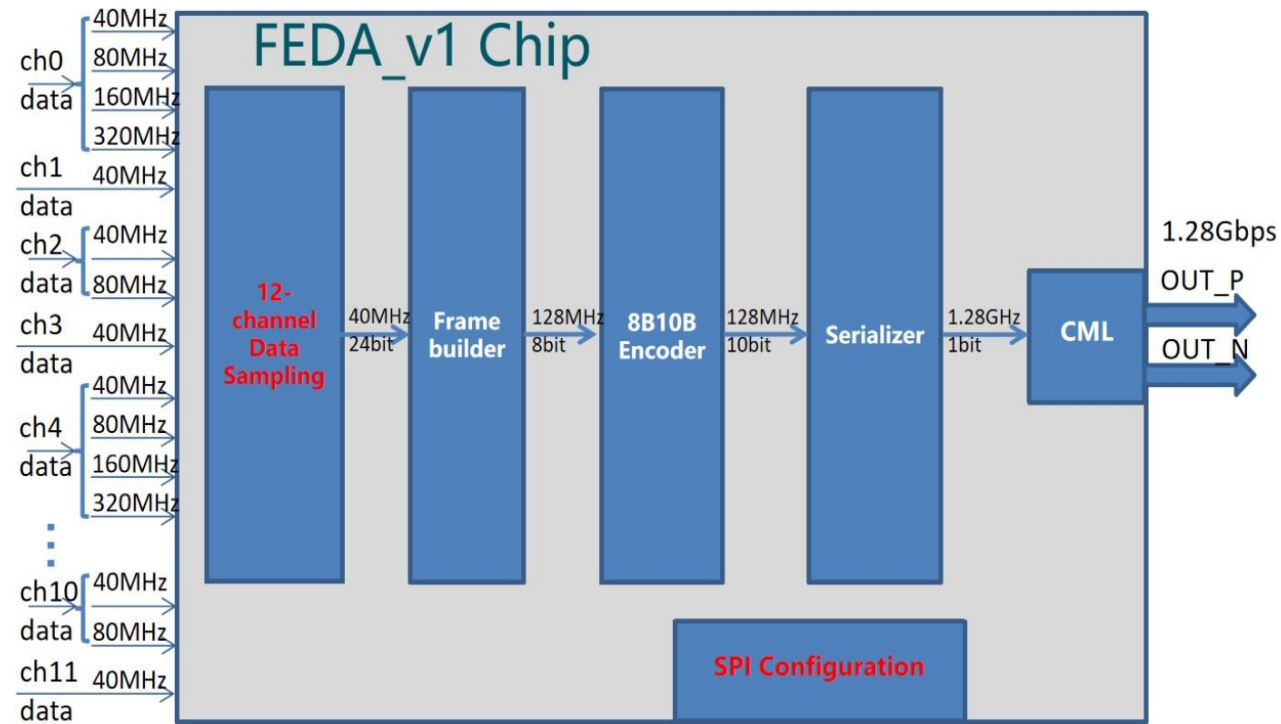
Ref. P. Moreira, GBT Chipset Status and Production Plans, 2013

Detailed design on Data Transmission Structure

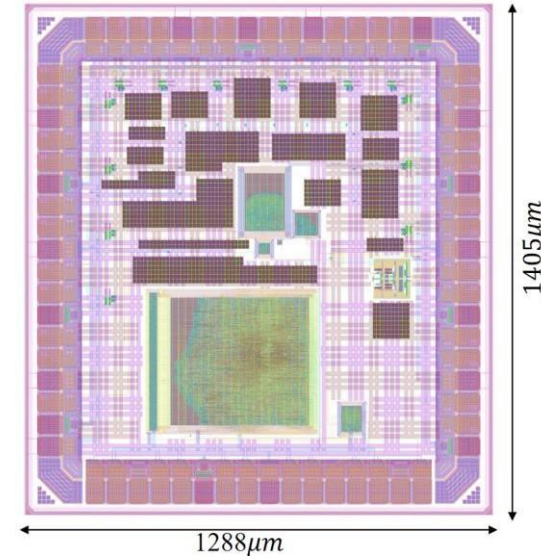


- Pre-Aggregation ASIC (FEDA): Intend to fit with different front-end detector (different data rates/channels)
- GBTx-like Data Link ASIC (FEDI): Bidirectional serdes ASIC including ser/des, PLL, CDR, code/decode ...
- Array Laser Driver ASIC (ALDD) + TIA ASIC (ATIA) + Customized Optical module (OAT)

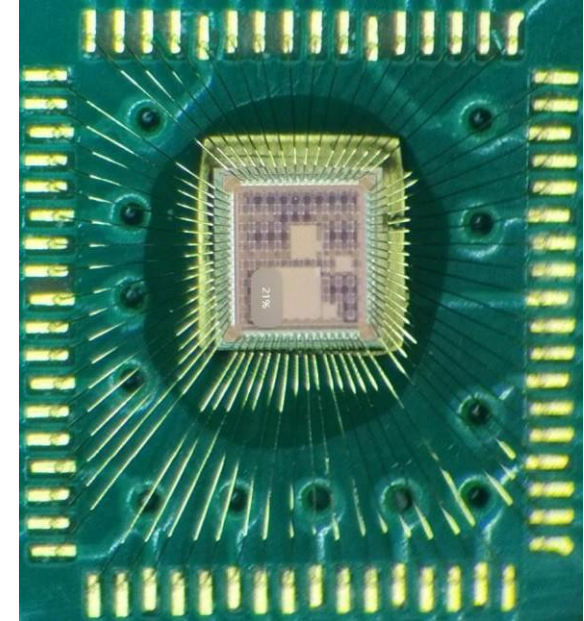
FEDA for data aggregation



FEDA block diagram



FEDA die layout

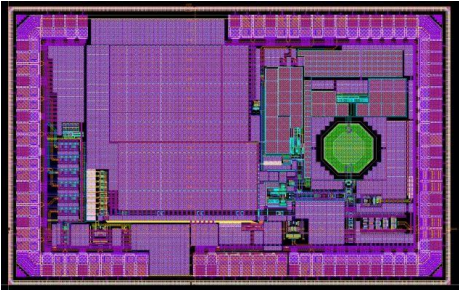
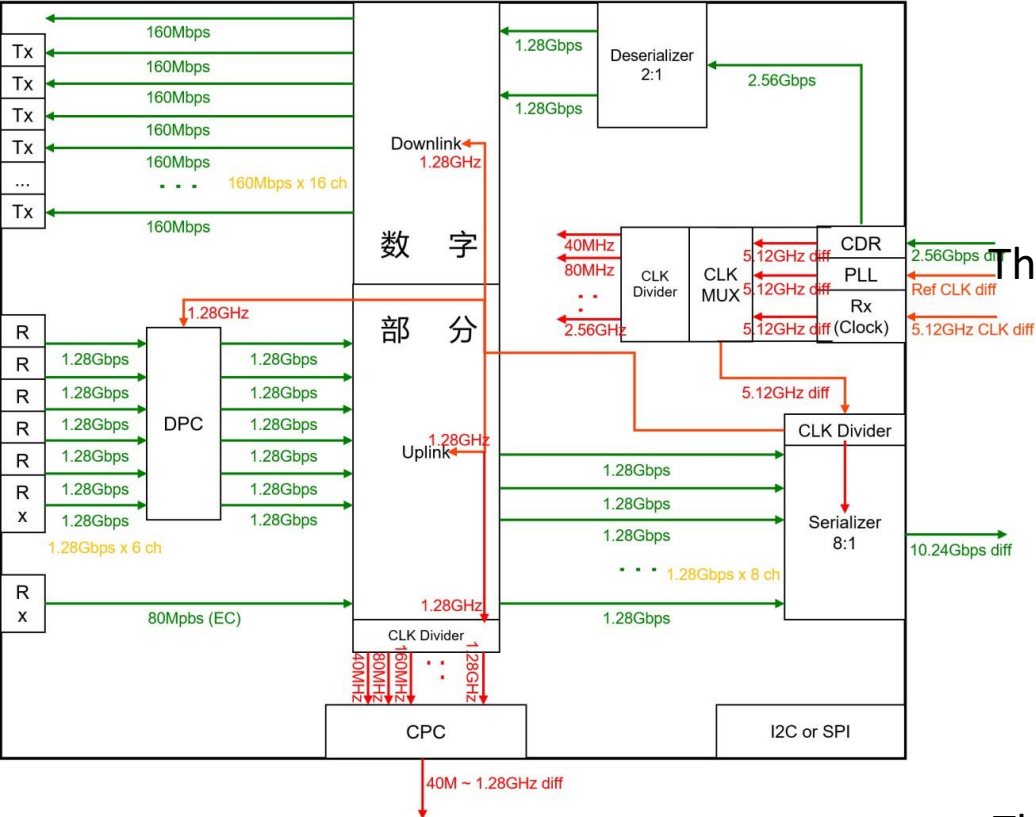


FEDA wire-bonded on PCB

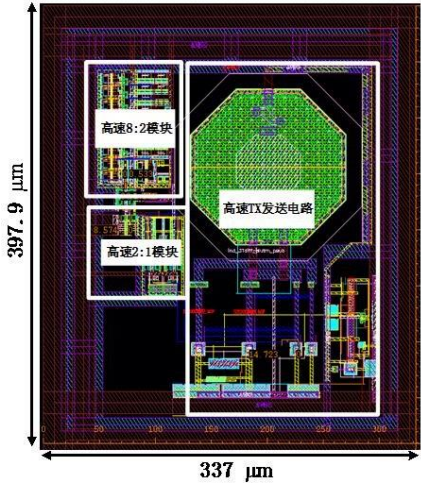
- Post-layout simulation has verified the functionality,
- The chip was taped out in Oct. 2025,
- Testing is on-going.

FEDI for data interface

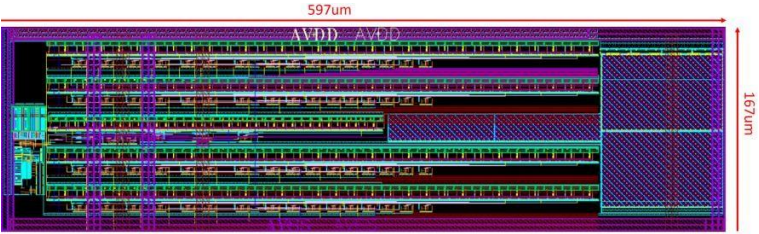
- The chip is in final integration & full chip verification phase
- To be tapeout in July 2026



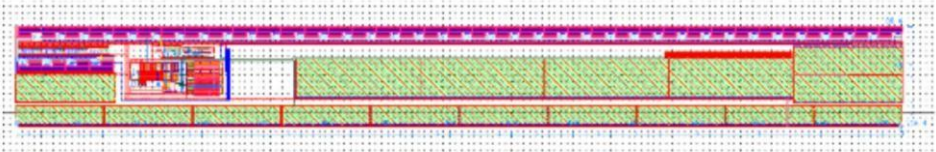
The high-speed clock module (95%)



The serializer、de-serializer module (90%)

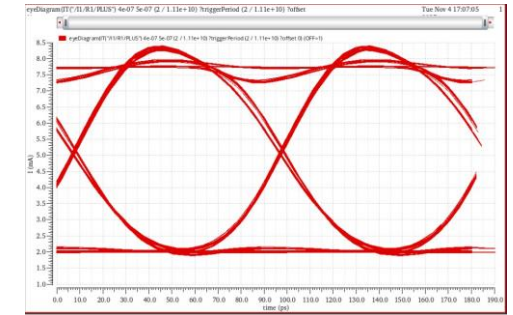
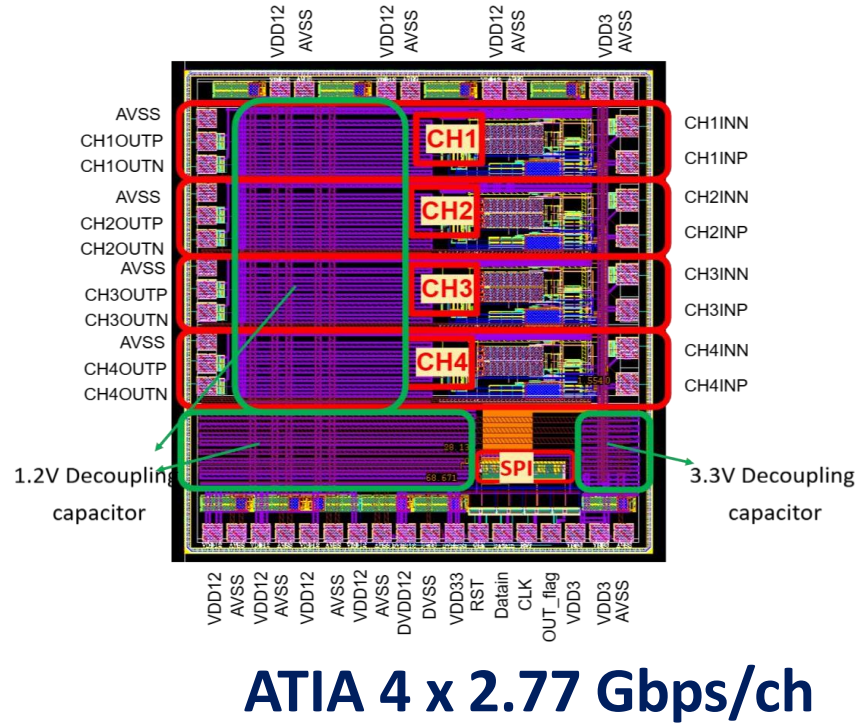
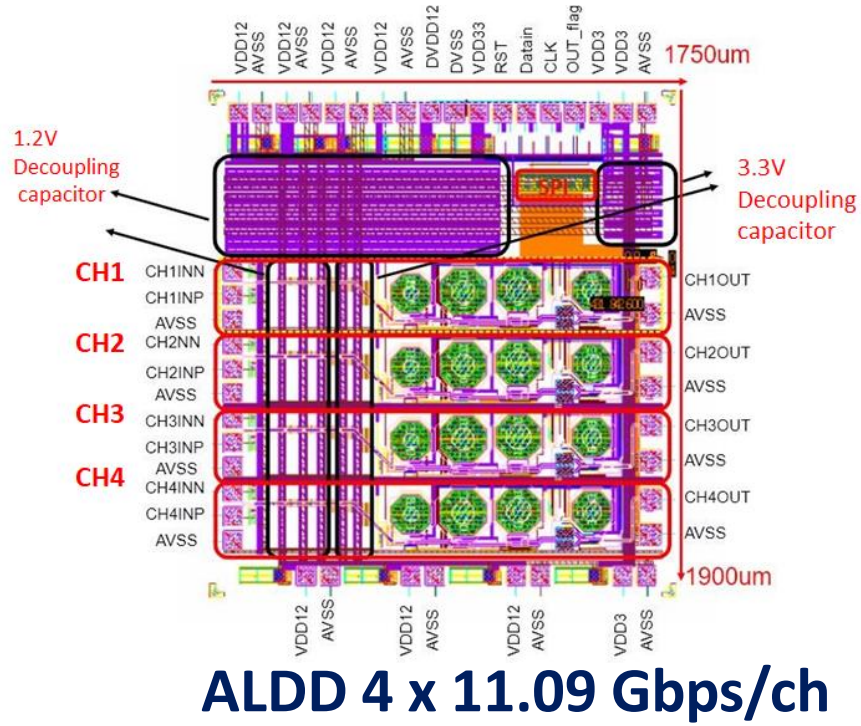


The data phase control module (90%)

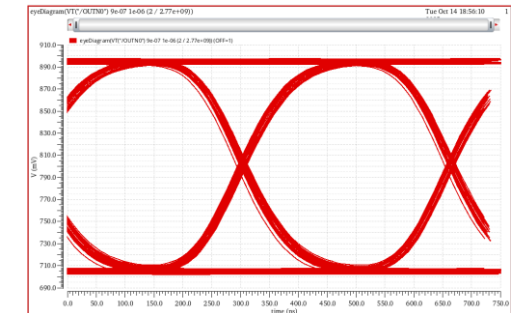


Layout Area: 716x80u
The clock phase control module (90%)

ALDD & ATIA for OAT, the opto- module

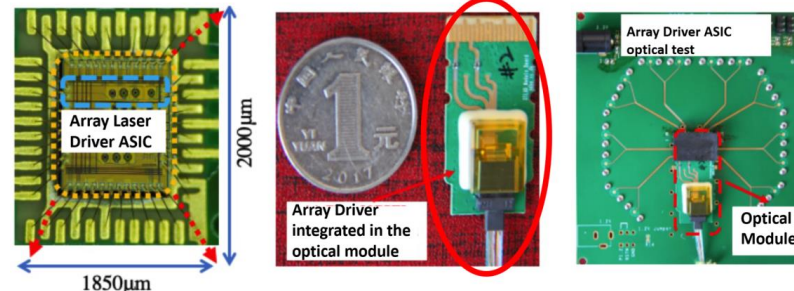


ALDD simulated eye diagram, post-layout, single channel



ATIA simulated eye diagram, post-layout, single channel

- ALDD & ATIA taped out in Oct. 2025.
- Test is on-going.



4 x 10 Gbps/ch VCSEL Array Driver with customized optical module

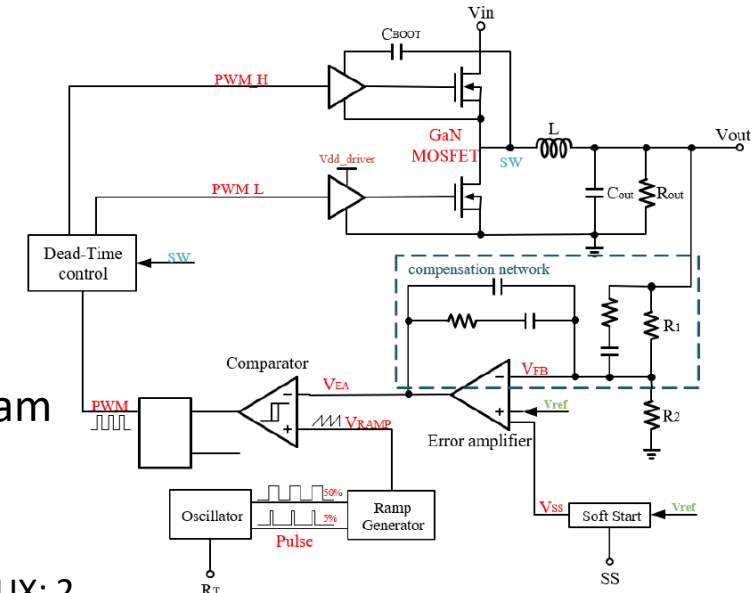
- Structure of the power distribution system

-
- The diagram illustrates the power supply architecture for the detector. It shows a hierarchical structure where a primary DC-DC converter (blue) provides a 10-12V output. This output is then distributed to three parallel branches, each containing a red DC-DC converter. The top branch provides 3.3V to a green DC-DC converter, which then outputs 1.2V/1V to the Digital Blocks. The middle branch provides 2.5V to a green DC-DC converter, which then outputs 1.2/1V to the Analog Block. The bottom branch provides 5/6V... to the Other Blocks. The Digital Blocks, Analog Block, and Other Blocks are grouped together in a dashed box labeled 'detector'.
- ```
graph LR; Input(()) --> DCDC1[DC-DC]; DCDC1 -- 10-12V --> DCDC2[DC-DC]; DCDC1 -- 10-12V --> DCDC3[DC-DC]; DCDC1 -- 10-12V --> DCDC4[DC-DC]; DCDC2 -- 3.3V --> DCDC5[DC-DC]; DCDC3 -- 2.5V --> DCDC6[DC-DC]; DCDC4 -- 5/6V... --> Other[Other Blocks]; DCDC5 -- 1.2V/1V --> Digital[Digital Blocks]; DCDC6 -- 1.2/1V --> Analog[Analog Block]; subgraph detector; Digital; Analog; Other; end
```

- ## ■ Proposed design of BUCK DC-DC convertor

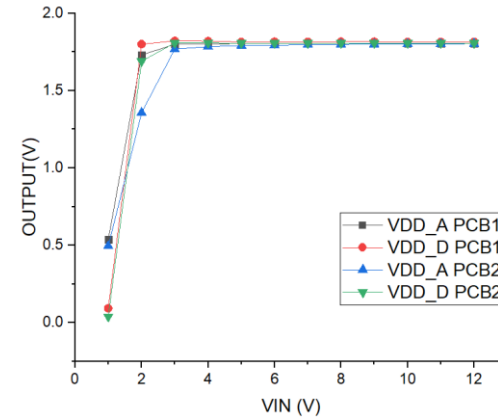
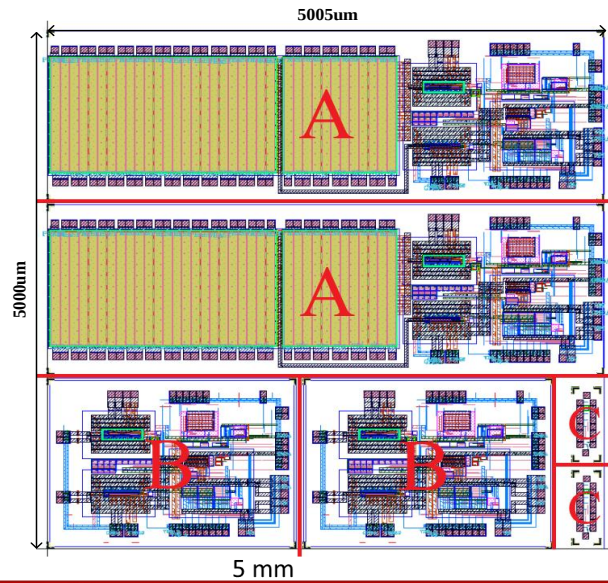


- Design team
  - IHEP: 3
  - NPU: 1+2
  - USTC: 1+1
  - TECHORILUX: 2

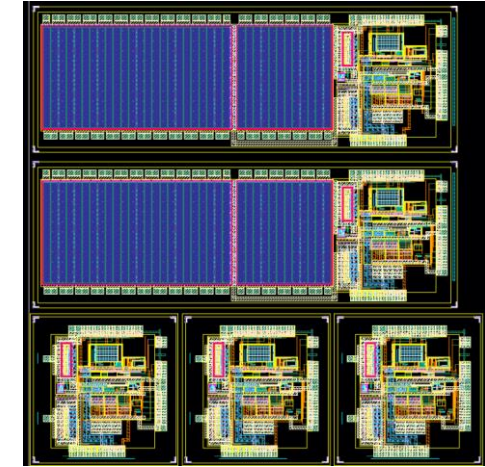




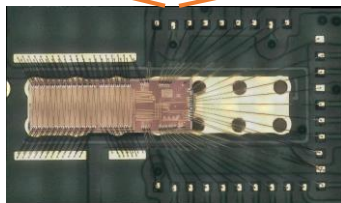
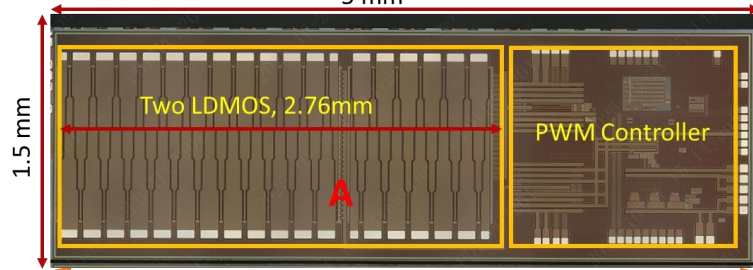
# PAL – DC-DC controller design



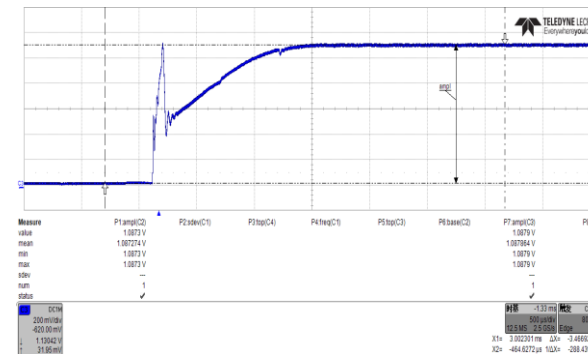
Supply analogue/digital power for controller (1.8V)



Revision tapeout in 2026



1<sup>st</sup> Tapeout in 2025



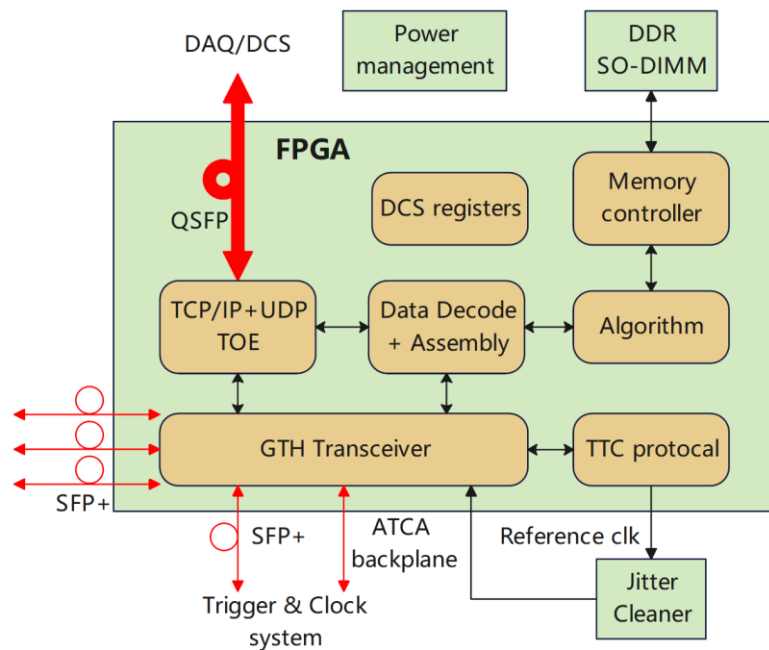
Transient Output

- Test with external Si/GaN power transistors continued
- Test done with the 1<sup>st</sup> tapeout, bugs detected and understood
- A revision tapeout submitted in Jan. 2026 to correct the issues

# ASIC development & teams

| Name    | Application | Functional       | Foundry & technology   | Similar chips | Leading person     | Development team          | Headcounts | Past tapeout times |
|---------|-------------|------------------|------------------------|---------------|--------------------|---------------------------|------------|--------------------|
| New-VTX | VTX         | VTX-Stitching    | Towerjazz 180nm (65nm) | MOSAIX        | Zhijun Liang(IHEP) | NPU, CCNU, SDU, NJU       | 18         | 3                  |
| TEPIX   | TPC         | Pixel TPC        | TSMC 180nm (65nm)      | Timepix3/4    | Zhi Deng (THU)     | IHEP                      | 5          | 2                  |
| COFFEE  | ITK         | HVCMOS           | SMIC 55nm HV           | MightyPix     | Yiming Li (IHEP)   | ZJU, NPU, DMU, SDU, NJU   | 20         | 3                  |
| LATRIC  | OTK         | LGAD-TOF         | SMIC 55nm              | ALTIROC       | Xiongbo Yan (IHEP) | CCNU, WTU, HPU            | 19         | 1                  |
| SIPAC   | SiPM ASIC   | ECAL, HCAL, Muon | SMIC 55nm              | HGCROC、SPIROC | Huaishen Li (IHEP) | CCNU, NPU                 | 11         | 1                  |
| FEDI    | Common Elec | Data Link        | SMIC 55nm              | lpGBT         | Di Guo (CCNU)      | IHEP, NPU, USTC, WTU, HPU | 25         | 1                  |
| OAT     | Common Elec | Optical          | SMIC 55nm              | VTRx+         | Di Guo (CCNU)      | IPAS, IHEP                | 6          | 0                  |
| FEDA    | Common Elec | Data Aggr.       | SMIC 55nm              | lpGBT         | Di Guo (CCNU)      | IHEP, NPU                 | 6          | 0                  |
| PAL     | Common Elec | DC-DC            | SMIC 180nm HV          | bPolx         | Jia Wang (NPU)     | IHEP, USTC, TECHORILUX    | 10         | 1                  |

# Detailed design on common BEE



Data aggregation and processing board  
Prototype for Vertex detector

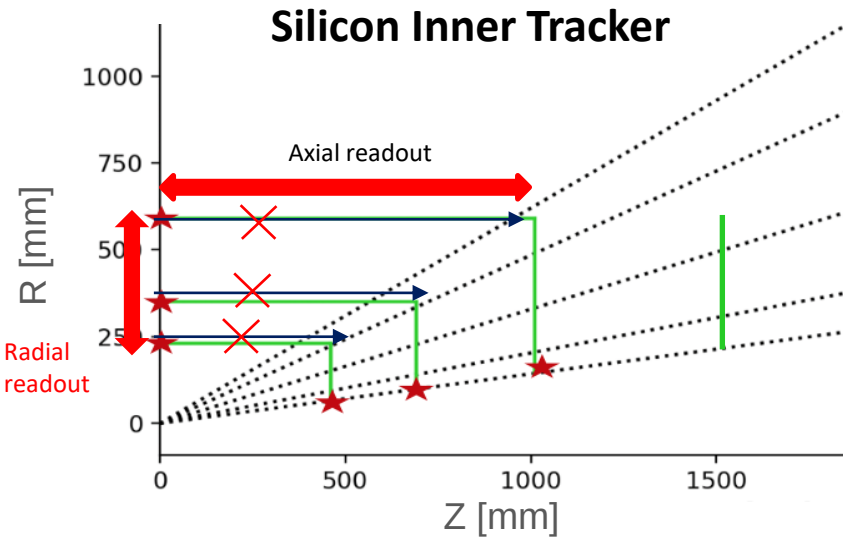
|                | KC705<br>(XC7K325<br>T-<br>2FFG900C) | KCU105<br>(XCKU040<br>-<br>2FFVA115<br>6E) | VC709<br>(XC7VX69<br>0T-<br>2FFG1761<br>C) | VCU108<br>(XCVU095<br>-<br>2FFVA210<br>4E) | XCKU115      |
|----------------|--------------------------------------|--------------------------------------------|--------------------------------------------|--------------------------------------------|--------------|
| Logic Cells(k) | 326                                  | 530                                        | 693                                        | 1,176                                      | 1451         |
| DSP Slices     | 840                                  | 1920                                       | 3,600                                      | 768                                        | 5520         |
| Memory (Kbits) | 16,020                               | 21,100                                     | 52,920                                     | 60,800                                     | 75,900       |
| Transceivers   | 16(12.5Gb/s)                         | 20(16.3Gb/s)                               | 80(13.1Gb/s)                               | 32(16.3Gb/s) and 32(30.5Gb/s)              | 64(16.3Gb/s) |
| I/O Pins       | 500                                  | 520                                        | 1,000                                      | 832                                        | 832          |
| Cost           | 2748 (650)                           | 3882(1500)                                 | 8094                                       | 7770                                       |              |

- Routing data between the optical link of front-end and the highspeed network of DAQ system.
- Connect to TTC and obtain synchronized clock, global control, and fanout high performance clock for front-end.
- Real-time data processing, such as trigger algorithm and data assembly.
- On-board large data storage for buffering.
- Preference for Xilinx Kintex UltraScale series due to its cost-effectiveness and availability.

- A cost-driven device selection: FPGA XC7VX690T
- Interface: SFP+ 10Gbps X12 + QSFP 40Gbps X3
- Implement real time FPGA based machine learning for clustering, hit point searching, and tracking algorithms



# Alternative scheme based on wireless communication



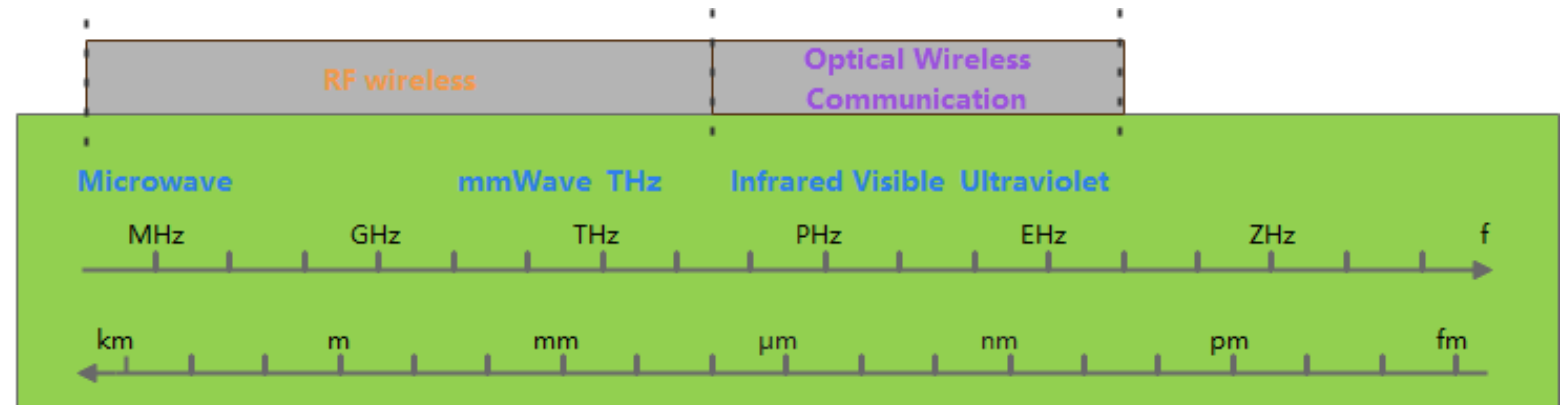
- **Radial readout** with mm-wave

- 12- 24 cm transmission distance
- Data rate : < 30Mbps

- Axial readout to endcap

- Only at the outermost layer or dedicated aggregation layer.

- Wireless communication based readout scheme was proposed to mitigate the cabling problem, as a backup scheme
- Three major solutions were investigated through R&D, two were selected with corresponding schemes
- R&D people-power in parallel with the main R&D



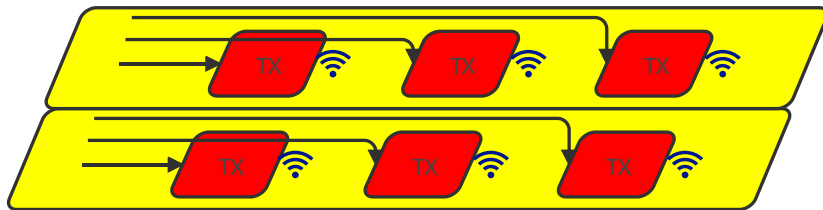
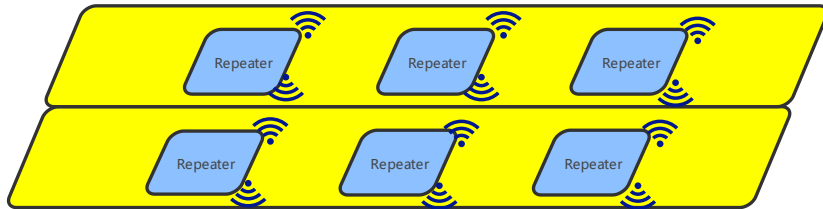
- WiFi (2.4GHz, 5GHz)

- large antenna volume, high power consumption, narrow frequency band, and high interference

- Millimeter Wave (24GHz, 45GHz, 60GHz, 77GHz)

- Optical wireless communication (OWC) / Free Space Optical (FSO)

# Recent progress on mm-wave transmission



Multi-channel Millimeter-Wave transmission prototype



Dummy Flex with MMW



MMW transmission module



FPGA data source board

- Single-channel MMW RX/TX verified
  - Max distance: 1.25Gbps @ 67.5cm
  - Max line rate: 6.6Gbps @ 22.5cm
- Multi-channel Millimeter-Wave transmission prototype in development
  - Millimeter-wave modules mass produced and tested
  - TX/RX flex PCBs and adapter boards produced, assembly in progress
  - FPGA data source board produced and tested
  - Repeater design: double-sided PCB, in progress
  - Focus: Multi-channel crosstalk validation

# Interface to the Electronics room

| Detector     | Max<br>Rate<br>Fiber (Gbps) | Data<br>per<br>Module | Fibers<br>per<br>Module | Fibers | BEEs | Crates |
|--------------|-----------------------------|-----------------------|-------------------------|--------|------|--------|
| VTX          | 8                           |                       | 1 - 2                   | 96     | 6    | 1      |
| TPC          | 0.1                         |                       | 1                       | 496    | 32   | 4      |
| ITK-Barrel   | 2.88                        |                       | 2 - 3                   | 376    | 24   | 2      |
| ITK-EndCap   | 4.4                         |                       | 2                       | 148    | 6    | 1      |
| OTK-Barrel   | 1.4                         |                       | 1                       | 880    | 55   | 4      |
| OTK-EndCap   | 1.4                         |                       | 1 - 2                   | 544    | 34   | 4      |
| ECAL-Barrel  | 4.8                         |                       | 4 (2)                   | 1,920  | 60   | 6      |
| ECAL-EndCap  | 4.8                         |                       | 4 (2)                   | 896    | 28   | 4      |
| HCAL-Barrel  | 0.14                        |                       | 1                       | 5,568  | 348  | 36     |
| HCAL-EndCap  | 1.75                        |                       | 1                       | 3,072  | 192  | 20     |
| Muon-Barrel  | 0.01                        |                       | 1                       | 24     | 2    | 1      |
| Muon-EndCap  | 0.01                        |                       | 1                       | 16     | 1    | -      |
| <b>Total</b> | -                           |                       | -                       | 14,036 | 788  | 83     |

| Detector     | Power<br>Composite Cables | Channels<br>Cables | / | Total<br>Power<br>(kW) | LV<br>Crates | LV<br>Crates | Max.<br>HV<br>(V) | HV<br>Crates |
|--------------|---------------------------|--------------------|---|------------------------|--------------|--------------|-------------------|--------------|
| VTX          |                           | 96                 |   | 0.45                   | 2            |              | -10               | 1            |
| TPC          |                           | 496                |   | 16                     | 6            |              | -500              | 4            |
| ITK-Barrel   |                           | 128                |   | 26.6                   | 6            |              | 300               | 2            |
| ITK-EndCap   |                           | 74                 |   | 13.8                   | 4            |              | 300               | 2            |
| OTK-Barrel   |                           | 880                |   | 195                    | 42           |              | 500               | 4            |
| OTK-EndCap   |                           | 288                |   | 60                     | 14           |              | 500               | 2            |
| ECAL-Barrel  |                           | 480                |   | 17.5                   | 5            |              | 60                | 4            |
| ECAL-EndCap  |                           | 224                |   | 9.5                    | 4            |              | 60                | 2            |
| HCAL-Barrel  |                           | 5,568              |   | 66.1                   | 58           |              | 60                | 26           |
| HCAL-EndCap  |                           | 3,072              |   | 41.3                   | 32           |              | 60                | 14           |
| Muon-Barrel  |                           | 24                 |   | 0.76                   | 1            |              | 60                | 1            |
| Muon-EndCap  |                           | 16                 |   | 0.45                   | 1            |              | 60                | -            |
| <b>Total</b> |                           | 11,346             |   | 447.46                 | 175          |              | -                 | 78           |

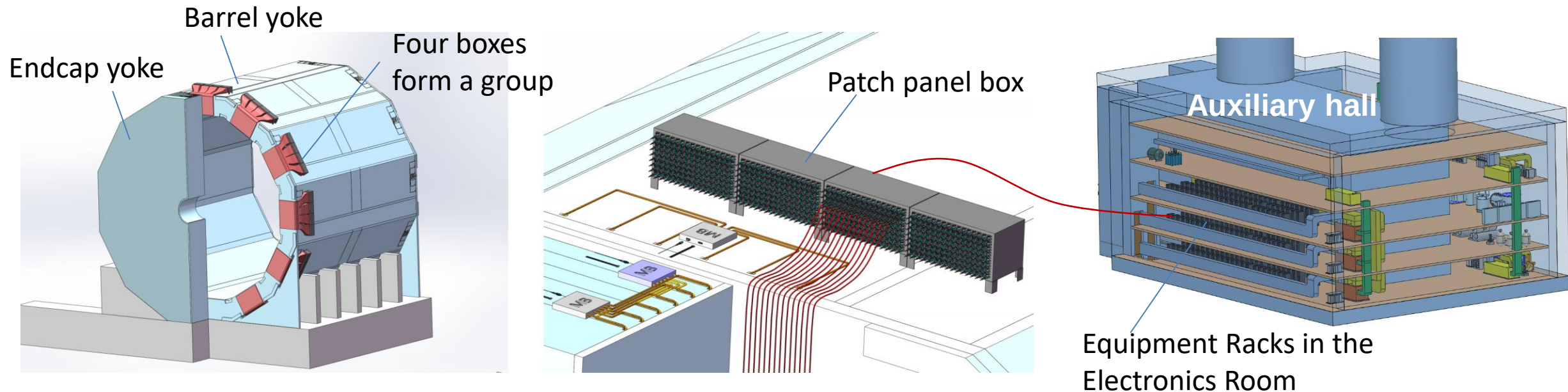
- Fiber/cable numbers updated(reduced) according to the latest detector design
- The on-detector connection described in each sub-D chapter, while the inter-detector connection newly described in the mechanical chapter
- The patch panel related interface newly described also in the mechanical chapter



# Integration with mechanics and Elec. room

## ■ How to handle the cables emerging from the yoke before reaching the electronics room?

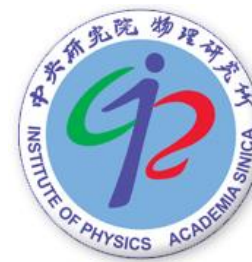
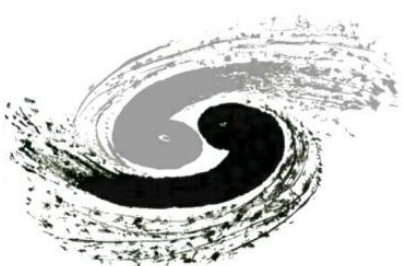
- Cable will be grouped and interconnected when emerging from the yoke
- All patch panel boxes are placed on the barrel yoke: allow for future endcap yoke access
- $11 \times 4 = 44$  boxes: bottom barrel yoke is inconvenient for cabling routing



Cables will undergo interconnection before reaching the electronics room

# Research team

- A wide collaboration was built involving most of the affiliations in the HEP field in China (~50 people involved in different areas).
- We are working to expand the collaboration, including attracting international colleagues. We are also trying to join in the DRD7.



- Overall electronics and BEE: IHEP(5)
- Sub-detector readout electronics: IHEP(11), Tsinghua(5), CCNU(3), NPU(7), SDU(4), NJU(3)
- Data link: CCNU(3), IHEP(3), USTC(2), NPU(4)
- Powering: NPU(3), IHEP(2), USTC(2)

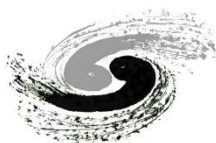
# Summary

- CEPC Reference TDR released and key R&D will continue to be prepared for the next 5-year plan
- Full Data Transmission (Frontend Triggerless) + Backend Trigger was chosen to be baseline for the 1<sup>st</sup> operational phase
  - Background rate under ctrl for Higgs & Low LumiZ
  - Backup scheme on Partial full data transmission + Partial fast trigger (VTX only if necessary)
- All ASIC design with dedicated people power, 1<sup>st</sup> / 2<sup>nd</sup> ver. of most ASIC taped out, still aiming at:
  - 3-year to prototype the ASIC
  - 5-year to be finalized
- Other key R&D to be kept on pace
  - Serial powering for future silicon detector
  - Wireless comm as an alternative scheme, while parallel people power allocated other than the main R&D





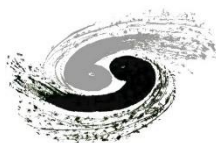
# Thank you for your attention!



中國科學院高能物理研究所  
*Institute of High Energy Physics*  
*Chinese Academy of Sciences*



# BACKUP



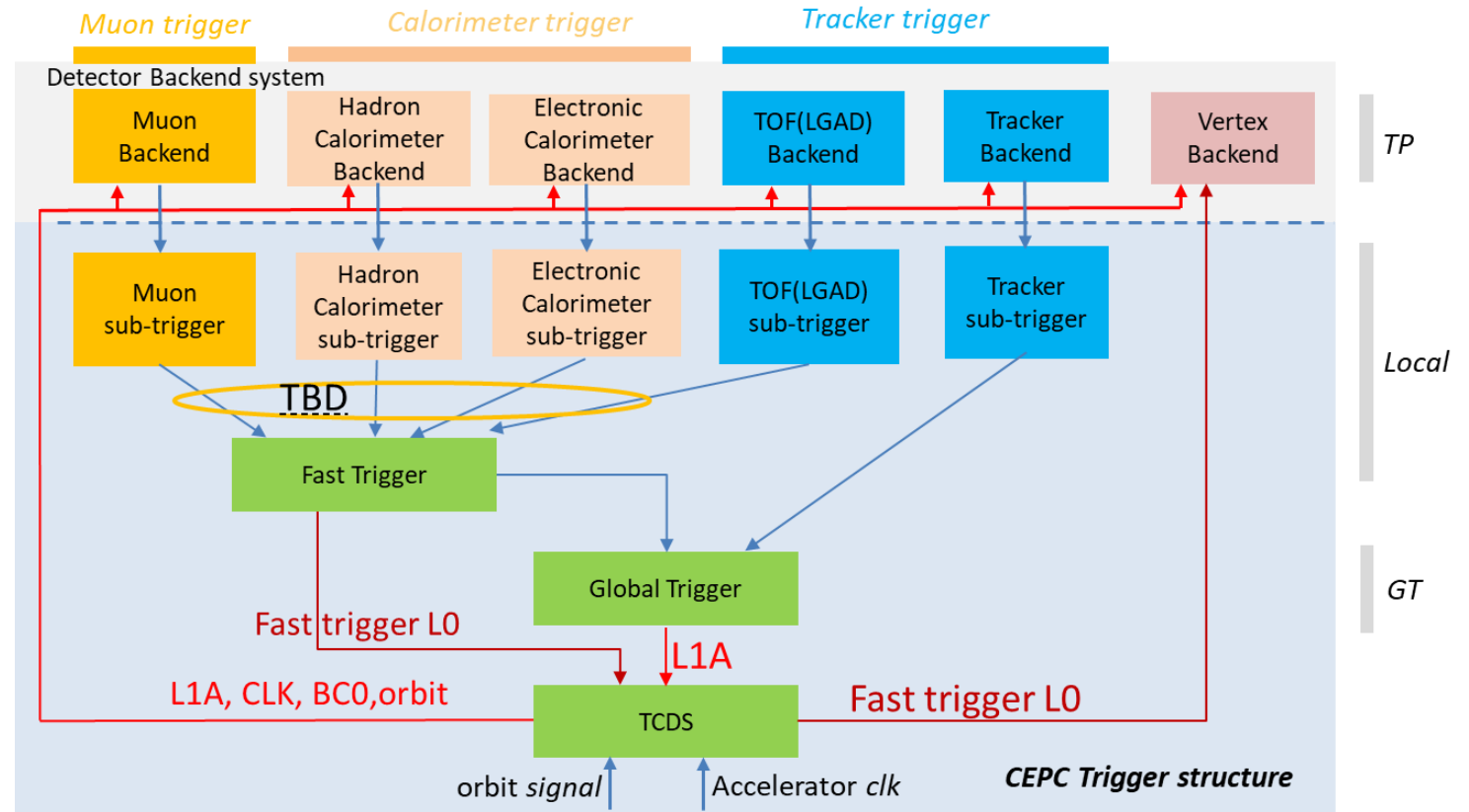
中國科學院高能物理研究所  
*Institute of High Energy Physics*  
*Chinese Academy of Sciences*

# Backup scheme of the framework

■ The proposed framework was based on the estimated background rate of all sub-det.

■ Background rate indicated the data link capability can manage the Phase I operation of Higgs & Low LumiZ in the first ten years

- Shielding optimization ongoing to suppress the background
- High LumiZ situation is still not fully understood, but in the 2<sup>nd</sup> ten years
  - Replaceable detectors e.g. VTX, ITK.. can be upgraded with new chips with intel-compression and advanced trigger in case
  - Unreplaceable detectors e.g. ECAL, HCAL can be upgraded with more fiber channels



The conventional trigger scheme can serve as a backup plan, with sufficient on-detector data buffering and reasonable trigger latency, the overall data transmission rate can be controlled.



# Consideration on global framework of Elec-TDAQ

- Two main stream frameworks for the electronics-TDAQ can be simply categorized as full data transmission (FEE-Triggerless readout) & readout with conventional trigger
- Comparison on main aspects

|                                    | Full data transmission    | Conventional Trigger       | Superiority            |
|------------------------------------|---------------------------|----------------------------|------------------------|
| Where to acquire trigger info      | On BEE                    | On FEE                     | Full data transmission |
| Trigger latency tolerance          | Medium-to-long            | Short                      |                        |
| Compatibility on Trigger Strategy  | Hardware / software       | Hardware only              |                        |
| FEE-ASIC complexity on Trigger     | Simple                    | Complex on algorithm       |                        |
| Upgrade possibility on new trigger | High                      | Limited                    |                        |
| FEE data throughput                | Large                     | Small                      | Conventional Trigger   |
| Maturity                           | Mature but relatively new | Very mature                |                        |
| Resources needed for calculation   | High                      | Low                        |                        |
| Representative experiments         | CMS, LHCb, ...            | ATLAS, BELLE2, BESIII, ... |                        |

# Our choice on global framework

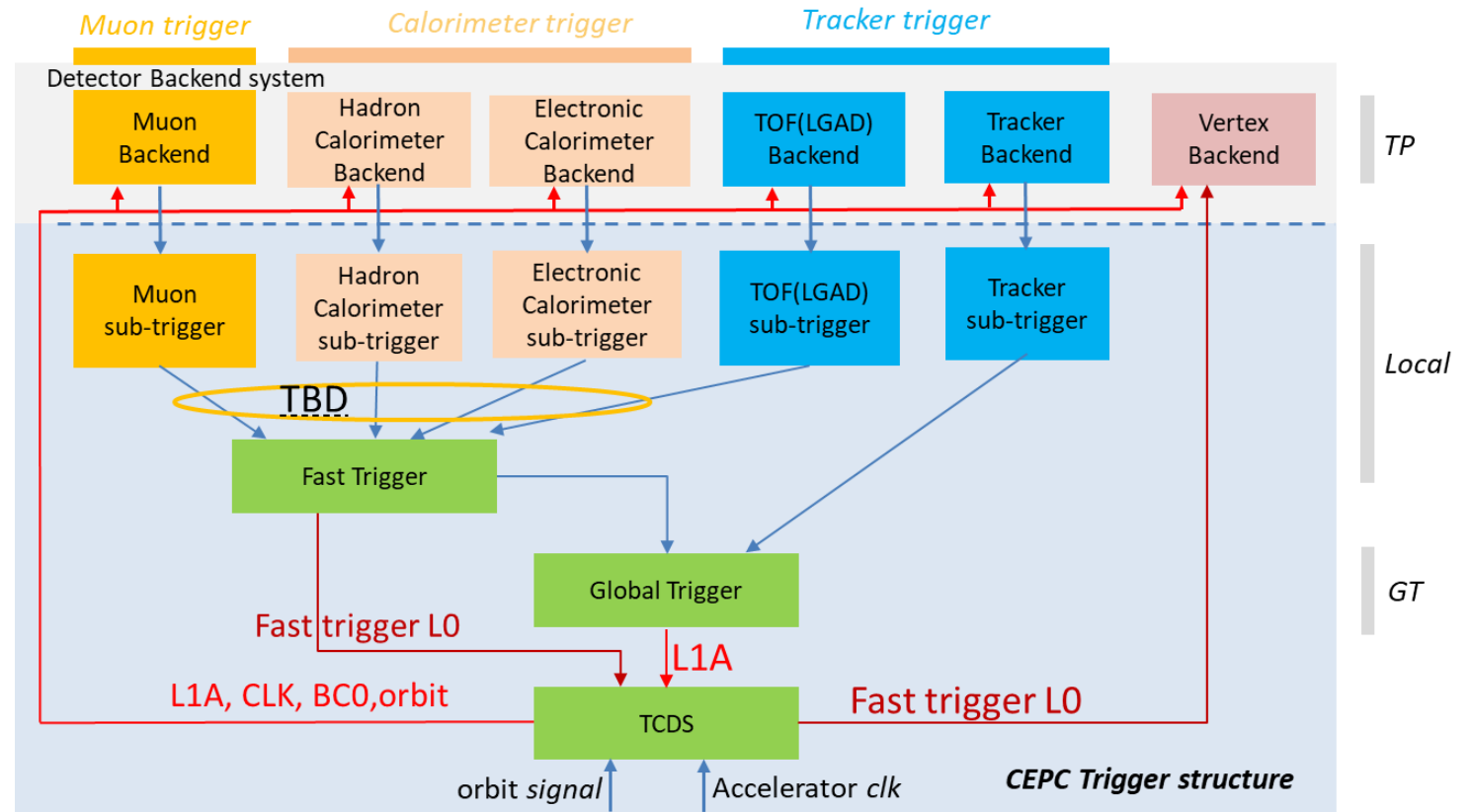
- We choose **Full Data Transmission (Frontend Triggerless) + Backend Trigger** as our baseline global framework, while keep conventional trigger (to be explained) readout as the backup :
  1. Maintain the maximum possibility for new physics and future upgrades.
    - Readout all the information w/o pre-assumed trigger conditions.
  2. Speed-up the FEE-ASIC iteration & finalization process
    - W/o the need to consider the undefined trigger algorithm, esp. regarding the potential tight schedule.
  3. Enable a common platform design for all Sub-Detectors
    - Common BEE Brd, common Trg Brd, common data interface...
    - Scalable based on the detector volume
  4. Sufficient headroom for FEE data transmission based on the current MDI background rate
    - 11Gbps per link on FEE (max by ×4 links)

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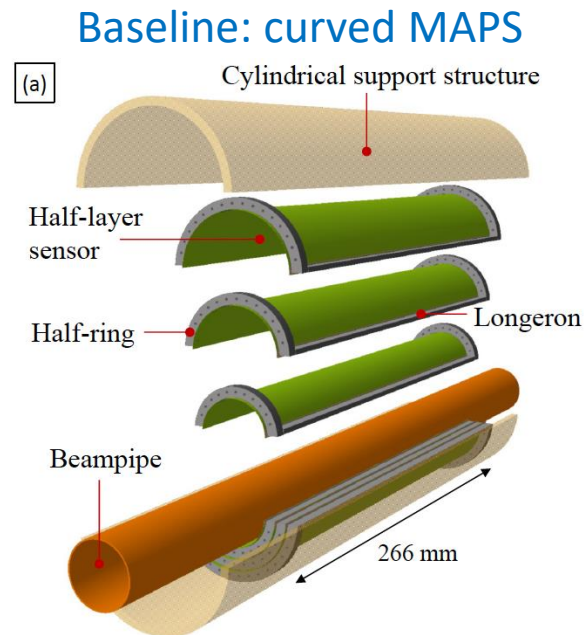
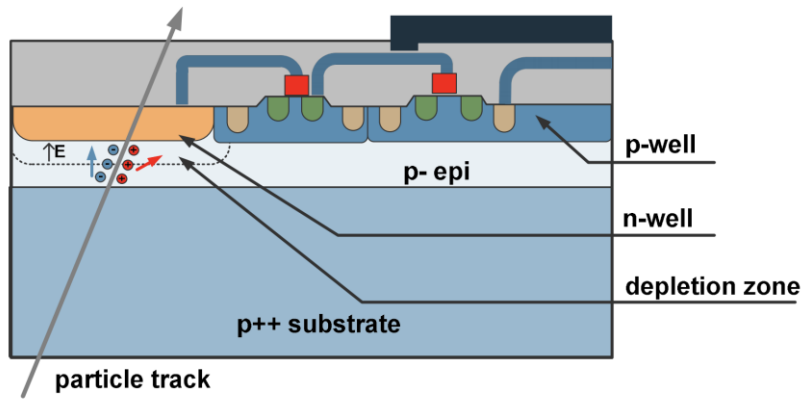
# Vertex Detector

## ■ Vertex detector Technology selection

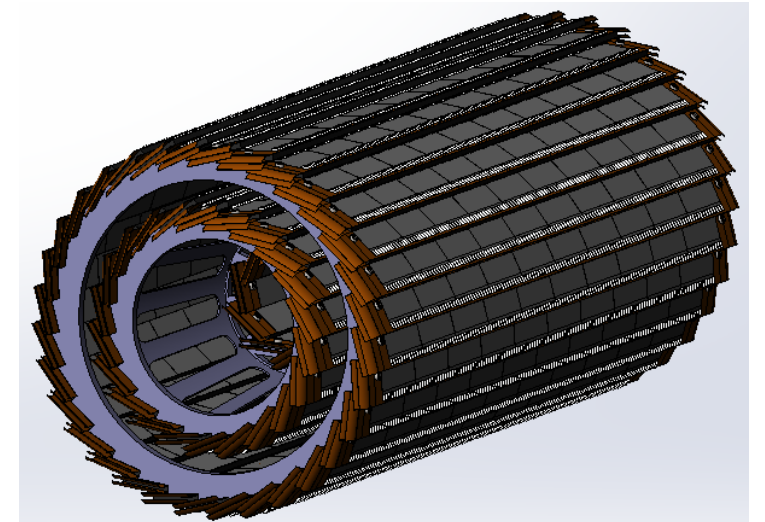
- Baseline: based on curved CMOS MAPS (Inspired by ALICE ITS3 design[1] )
  - Advantage: 2~3 times smaller material budget compared to alternative (ladder)
- Alternative: Ladder design based on CMOS MAPS

Monolithic active Pixel CMOS (MAPS)

### Monolithic Pixels



Alternative: ladder based MAPS



[1] ALICE ITS3 TDR: <https://cds.cern.ch/record/2890181>

# Choice of technology for next R & D

- Next step foundry: SK hynix system fab in Wuxi China (90nm technology with stitching feasibility)

|                             | Requirements                       | TPSCo 65 nm                 | HLMC 55 nm                                    | HC90L                                                                                 |
|-----------------------------|------------------------------------|-----------------------------|-----------------------------------------------|---------------------------------------------------------------------------------------|
| Feature size                | 55 – 90 nm                         | 65 nm                       | 55 nm                                         | 90 nm                                                                                 |
| Epitaxial layer thickness   | 10 - 25 $\mu\text{m}$              | 10 $\mu\text{m}$            | 3-5 $\mu\text{m}$                             | 4 – 8.5 $\mu\text{m}$ (default)<br>Can be changed to 20 $\mu\text{m}$                 |
| Resistivity of epi-layer    | > 1 $\text{k}\Omega\cdot\text{cm}$ | ~130 $\Omega\cdot\text{cm}$ | Low resistivity<br>~10 $\Omega\cdot\text{cm}$ | 30-50 $\Omega\cdot\text{cm}$ (default)<br>Can upgraded to 5 $\text{k}\Omega\text{cm}$ |
| Availability of deep N-well | Yes                                | Yes                         | Yes                                           | Yes                                                                                   |
| Availability of deep P-well | Yes                                | Yes                         | Yes                                           | Optional                                                                              |
| Numbers of metal layers     | > 6                                | Max. 7                      | Max. 5                                        | Max. 5                                                                                |
| Availability of stitching   | Yes                                | Yes                         | Yes                                           | Yes                                                                                   |
| Cost “ratio”(NRE)           |                                    | 1                           | 0.85                                          | 0.3                                                                                   |

# ITK Barrel Design with HV-CMOS Pixels

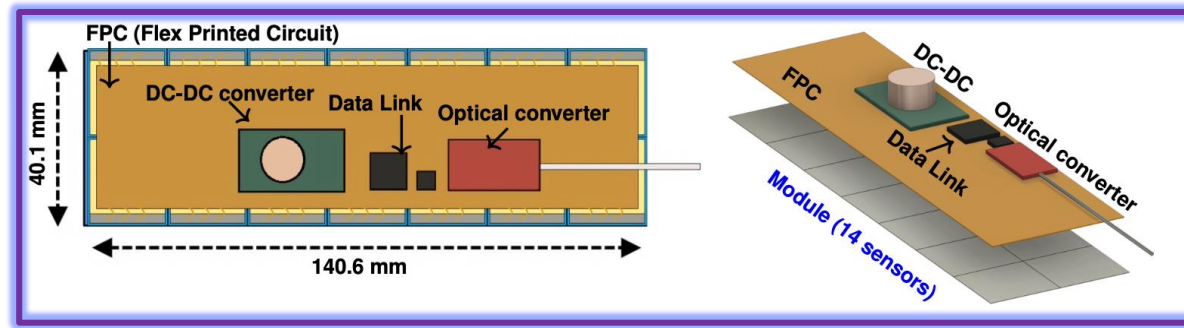


Figure 5.37

- HV-CMOS pixel sensor:
  - Sensor size: 20 mm × 20 mm
  - Pixel size: 34  $\mu\text{m}$  × 150  $\mu\text{m}$  (spatial resolution: 8  $\mu\text{m}$  × 40  $\mu\text{m}$ )
- Module:
  - 14 sensors (2 rows × 7 columns)
  - Module dimensions: 140.6 mm × 40.1 mm
- Stave length: 986.6 mm (ITKB1), 1,409.6 mm (ITKB2), and 1973.2 mm (ITKB3)
- Barrel radii: 235 mm (ITKB1), 345 mm (ITKB2), and 555.6 mm (ITKB3)

## 5.3.2.1 ITK barrel design

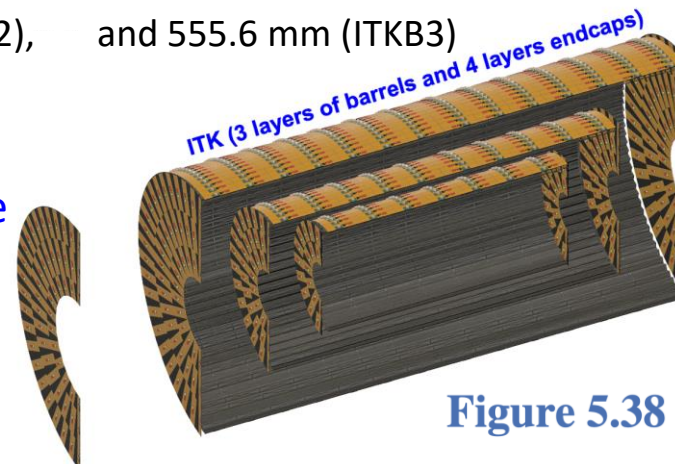
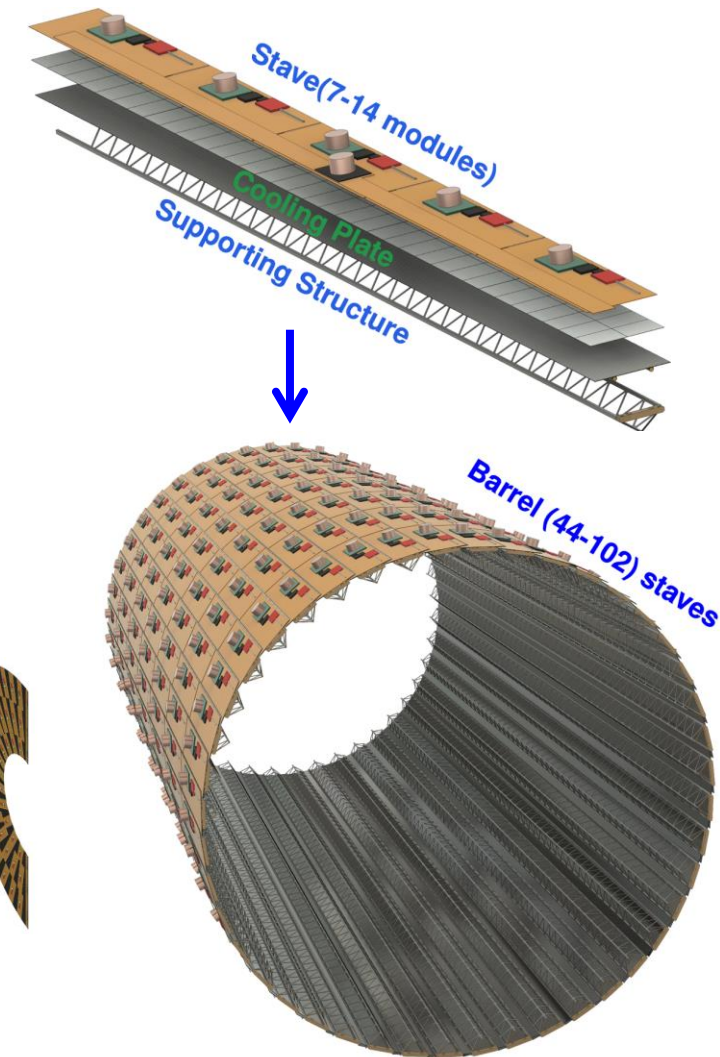


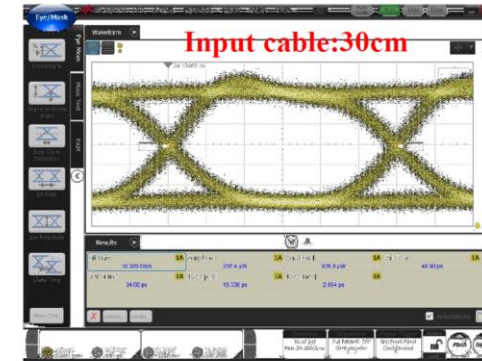
Figure 5.38

The designed 3 ITK barrel layers has a total surface area of 13.3 m<sup>2</sup>, including 33,264 sensor chips, with a power consumption of ~26.6 kW.



# R&D efforts and results on Data Link

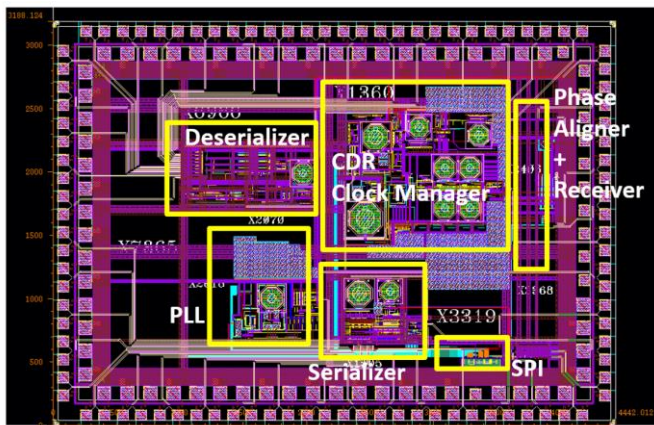
- Self-developed GBT-like prototypes verified:
  - 5.12 GHz PLL + 10.24 Gbps Serializer **verified✓**
  - 2.56 Gbps CDR + 2.56 Gbps Deserializer **verified✓**
  - Phase aligner **under test**
- 10 Gbps Laser Driver **Verified ✓**
- Customized optical module prototype **Done ✓**
- The rad-tol fiber will be investigated together with the accelerator clocking system



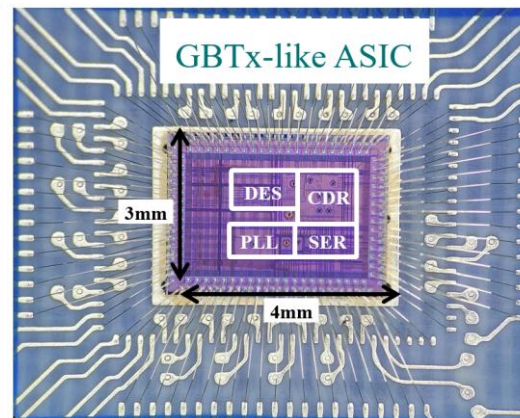
|           |        |      |         |
|-----------|--------|------|---------|
| Bit Rate  | 10Gbps | RMSJ | 2.6ps   |
| Rise Time | 34.0ps | PPJ  | 15.3ps  |
| Fall Time | 48.9ps | Amp  | 589.4μW |

10 Gbps optical eye diagram

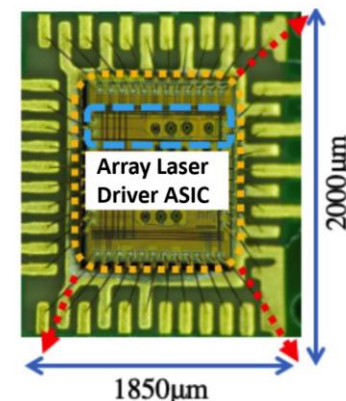
Customized Optical module



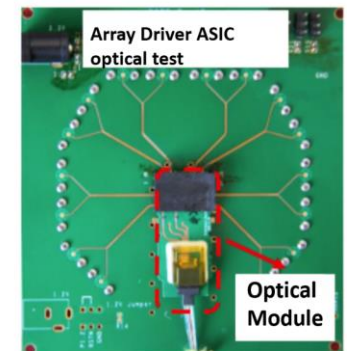
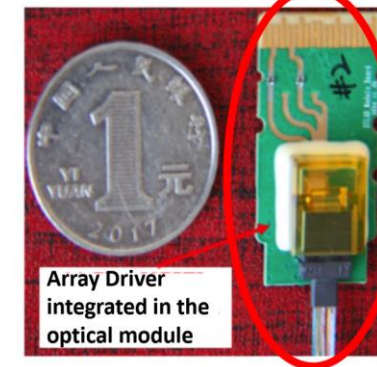
GBT-like ASIC prototype layout



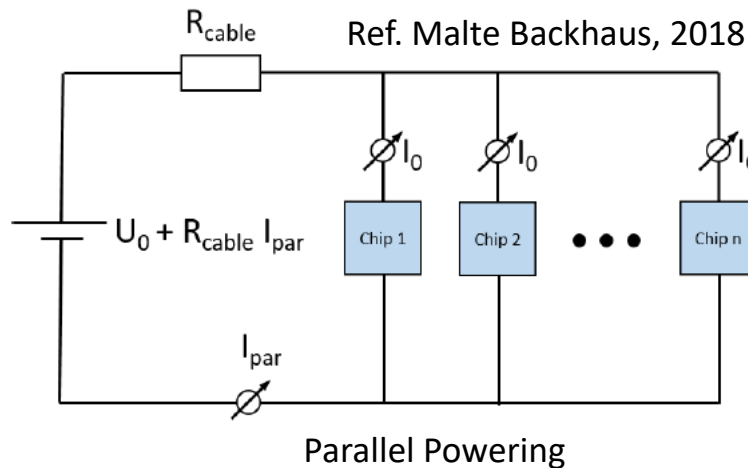
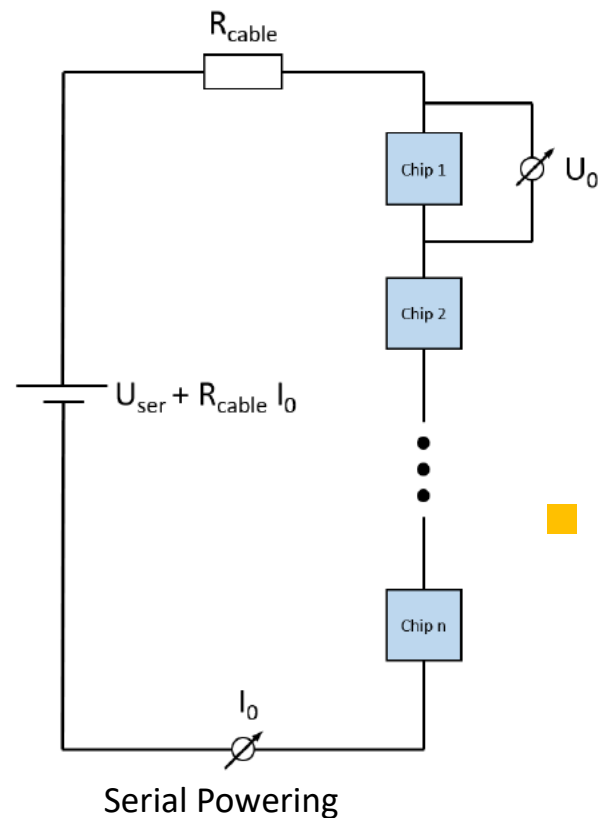
GBT-like ASIC wire-bonding picture



4 x 10 Gbps/ch VCSEL Array Driver with customized optical module



# Technology survey and our choice on Powering



|                    | Serial Power    | Parallel Power |
|--------------------|-----------------|----------------|
| Material           | Much less       |                |
| Cabling            | Much less       |                |
| Installation       | Much easier     |                |
| Maturity           | New             | Very mature    |
| System Reliability | Potential issue | Very robust    |

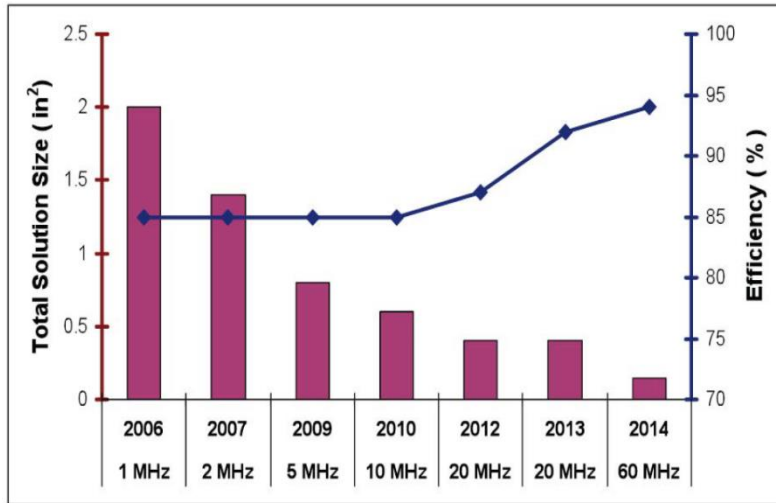
## ■ On powering distribution

- Serial Powering is superior in many aspects (material, cabling and installation...) than Parallel Powering, especially on VTX & TRK
- It is also a hot area with a lot of focused R&D
- However, due to the **common substrate at negative voltage for the stitching sensor in VTX**, serial powering is not feasible

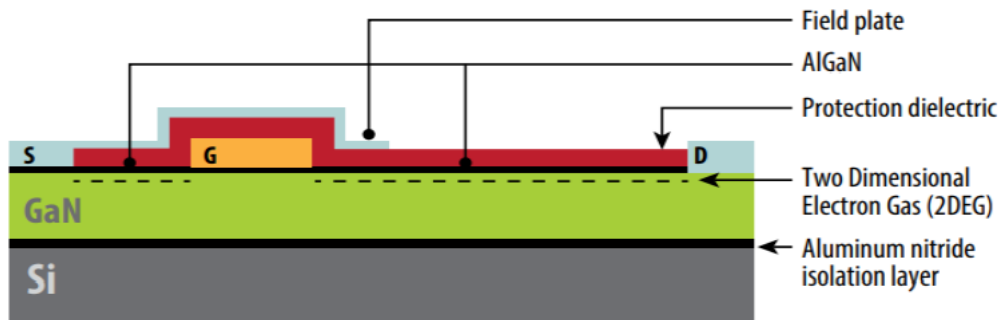
## ■ Our choice

- As a general platform, we chose (conventional) Parallel Powering as the baseline scheme, while to keep pace on R&D of Serial Powering as the backup scheme

# Technology survey and our choice on Powering



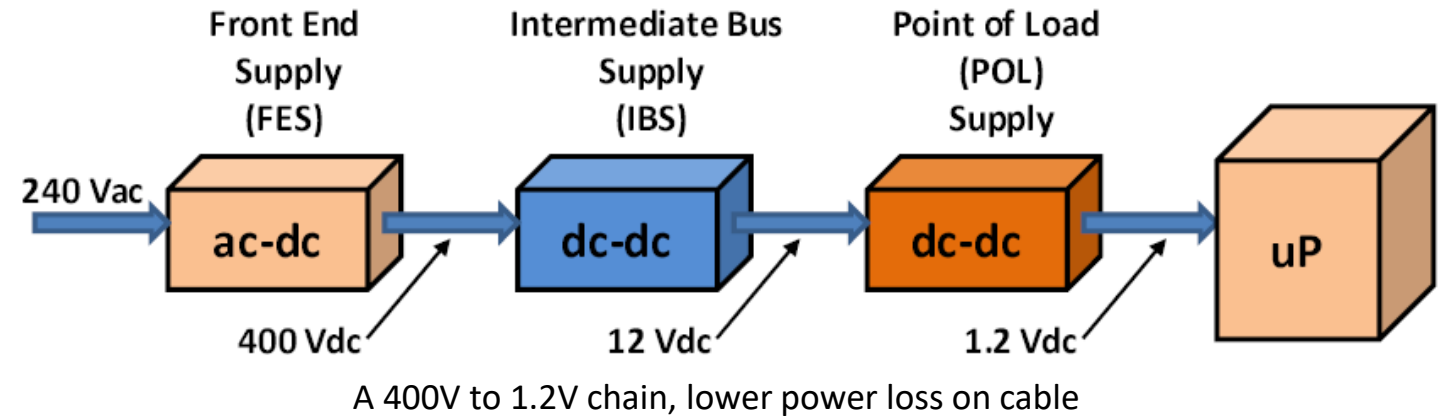
Higher switching Freq, smaller size,  
higher efficiency, lower on-resistance



Increased radiation hardness (no SiO<sub>2</sub>, responsible for most TID effects in Si MOSFETs, in contact with the channel)

Ref. Satish K Dhawan, 2010

Ref. S. Michelis, Prospects on the Power and readout efficiency



- Investigation was also conducted to compare the key component schemes of the power module, esp on LDO & DC-DC convertor.
- The GaN transistor has been a game changer in recent years, enabling DC-DC converters to achieve ultra-high efficiency, high radiation tolerance, and noise performance comparable to LDO.
- We choose a **GaN-based DC-DC as the baseline power module scheme**. This also enables high voltage power distribution, for low cable material and low power loss.



# Electronics in the counting room

## ■ Minimum crates from current MDI

- 83 data crates, 175 LV power crates, 78 Det-HV crates, 20 Trigger crates

## ■ Minimum racks from current MDI

- 27 data racks, 24 power racks, 26 Det-HV racks, 10 trigger racks (94 in total)
- More 2 racks for AC-DC power for all the above racks
- 96 racks in total

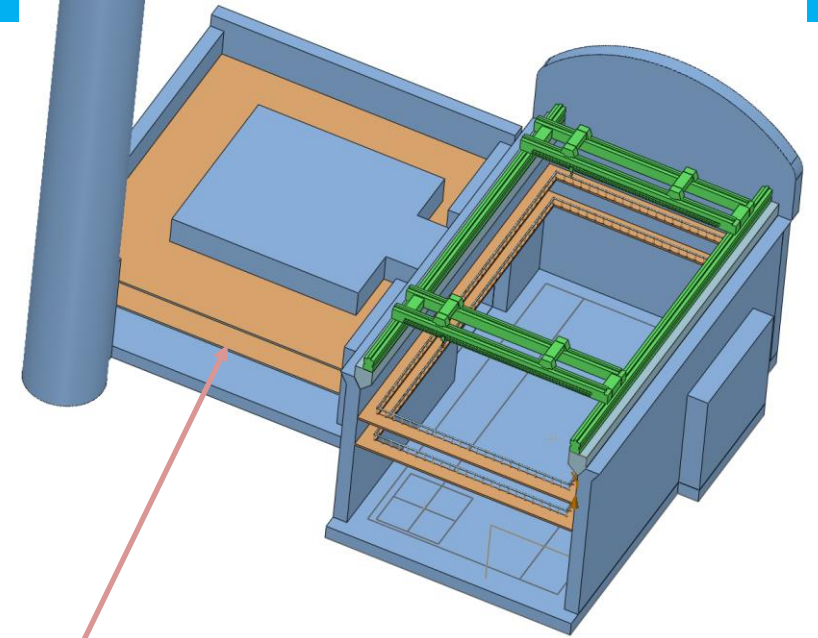
## ■ Racks Size: 0.5m × 0.5m

## ■ Side clearance 1.5m for heat, face clearance 2m for cabling & heat

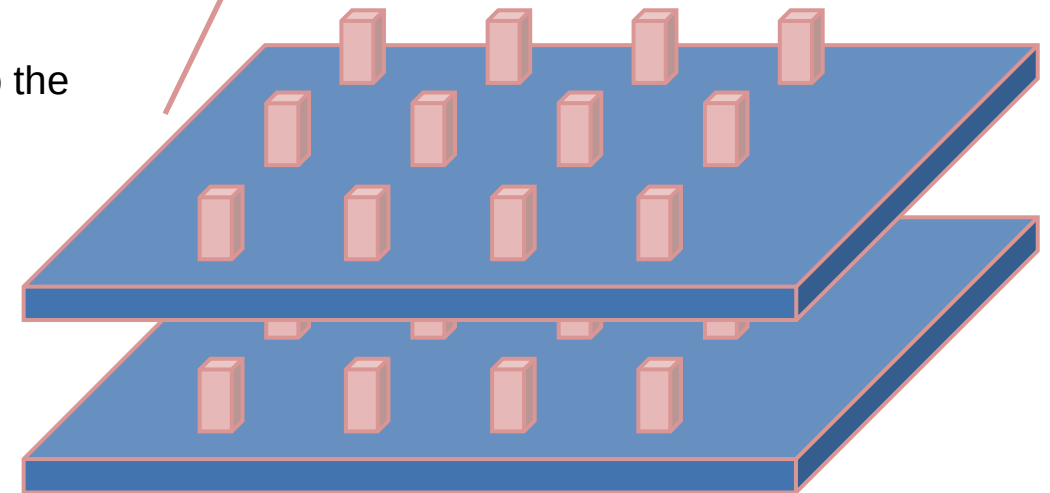
- Very rough estimation: 20% more power will be consumed due to the crate efficiency

## ■ Total room: $500\text{m}^2 \times 2\text{floor} = 25\text{m} \times 20\text{m} \times 2\text{floor}$

- $10 \times 10 \times 2 = 200$  racks capacity
- Necessary redundancy for future upgrade

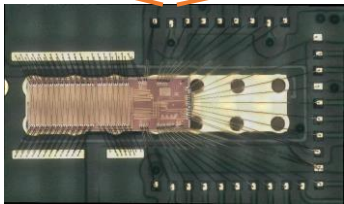
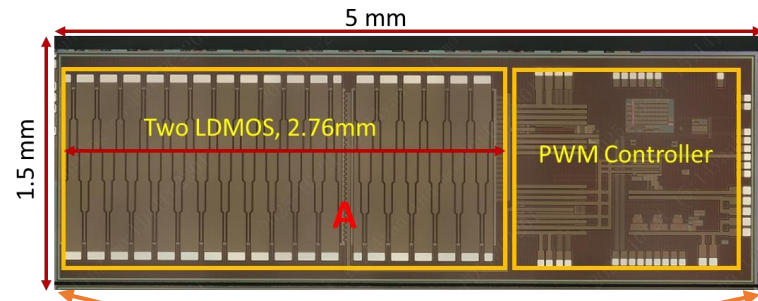


See Quan Ji's talk on Mechanics



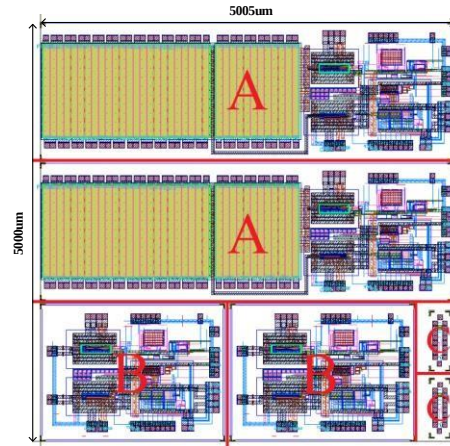
# DC-DC controller

The tape-out in January 2025

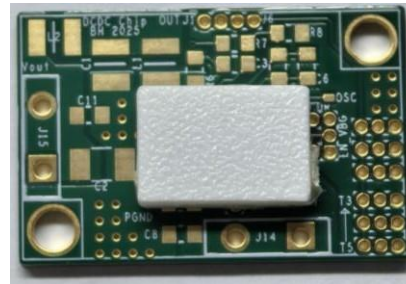


Die wire-bonded on a PCB

The built-in power transistor does not work stably, problem identified. Tests continued with an external Si power transistor. The PCBs for tests with GaN power transistors are received from the wire-bonding house. Tests are starting.



The layout

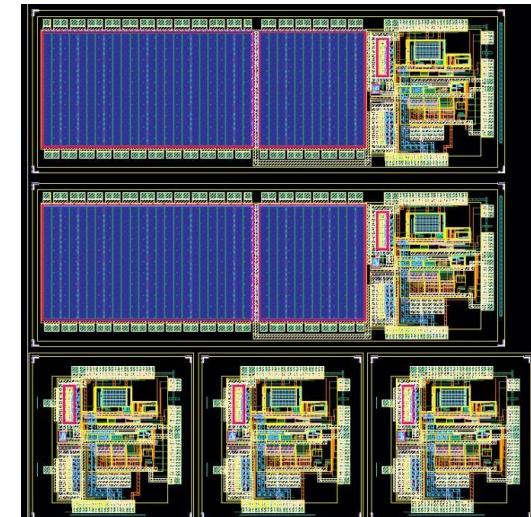


Test PCB

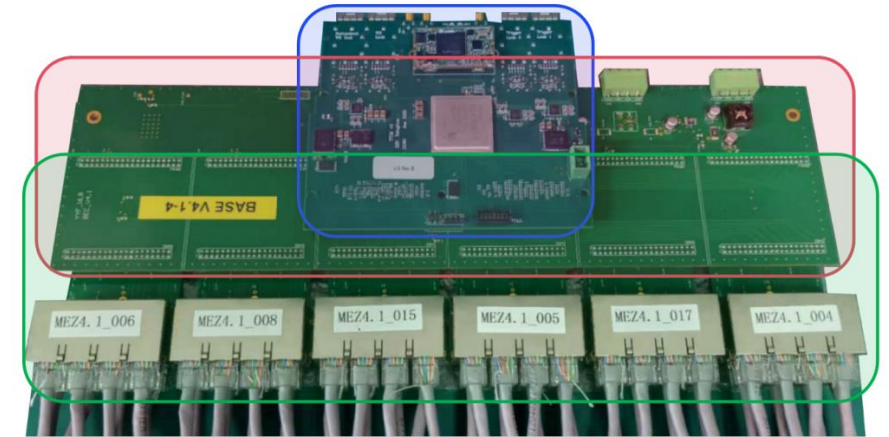
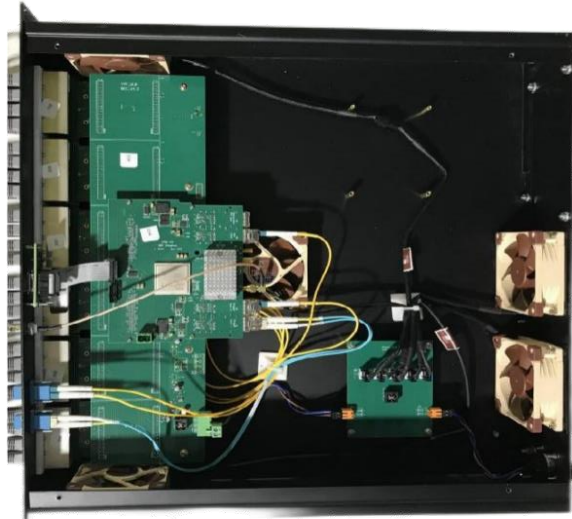
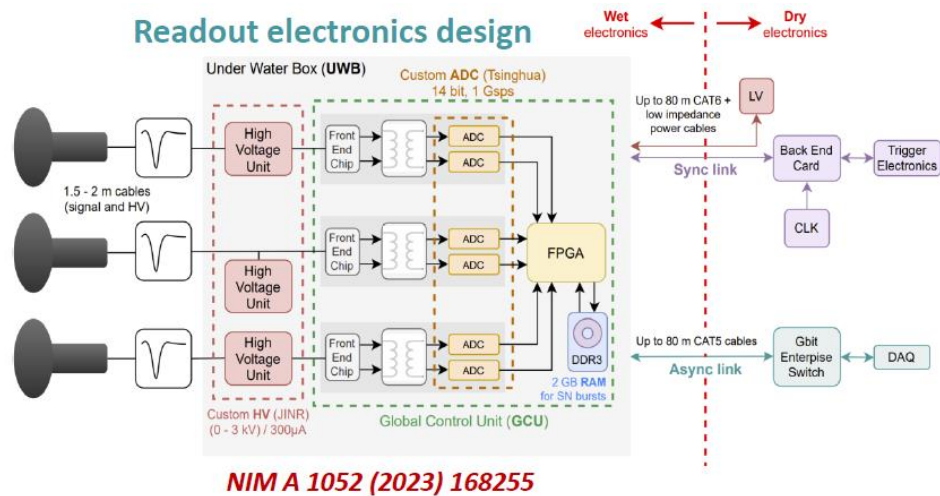
The tape-out in January 2026

changes:

1. Correct the problem in the built-in power transistor to avoid current leak.
2. ESD protection only to GND
3. Removed the enabling circuit to the band-gap.
4. Improved powering up sequence, and added pre-power-drop circuit.
5. Die size reduces from  $2.17 \times 1.48 \text{ mm}^2$  to  $1.38 \times 1.42 \text{ mm}^2$
6. Test points for irradiation.



# Related R&D and experience on BEE



The back-end box for the JUNO experiment

- located between trigger system and front-end electronics,
- Collects the incoming trigger request for trigger system,
- Fanout the synchronized clock and the trigger decisions to front-end electronics.

- Red box: The base board provides the power supply,
- Blue box: Trigger and Time Interface Mezzanine (TTIM) with WR node,
- Green box: The extenders interface with ethernet cables coming from underwater front-end boxes.



# People-power for Electronics system

|                      | Overall | BEE | VTX | TPC | ITK+OTK<br>(LATRIC) | CAL<br>(SiPM) | Muon | Data<br>Link | Power | Wireless |
|----------------------|---------|-----|-----|-----|---------------------|---------------|------|--------------|-------|----------|
| Staff                | 5       | 1   | 10  | 1   | 9                   | 5             | 1    | 9            | 7     | 4        |
| Postdoc +<br>Student | 0       | 3   | 8   | 4   | 10                  | 6             | 0    | 16           | 3     | 5        |
| Total Sum            | 5       | 4   | 18  | 5   | 19                  | 11            | 1    | 25           | 10    | 9        |

- The headcounts are not to the FTE
- Some staffs are shared by multiple projects, while postdocs / students are dedicated to the projects

# Affiliations for Electronics system

|          | Overall | BEE | VTX | TPC | ITK+OTK<br>(LATRIC) | CAL<br>(SiPM) | Muon | Data Link | Power | Wireless |
|----------|---------|-----|-----|-----|---------------------|---------------|------|-----------|-------|----------|
| IHEP     | ×       | ×   | ×   |     | ×                   | ×             | ×    | ×         | ×     | ×        |
| CCNU     |         |     | ×   |     | ×                   | ×             |      | ×         |       |          |
| THU      |         |     |     | ×   |                     |               |      |           |       |          |
| NPU      |         |     | ×   |     |                     |               |      | ×         | ×     |          |
| NJU      |         |     | ×   |     | ×                   |               |      | ×         |       |          |
| USTC     |         |     |     |     |                     |               |      | ×         | ×     |          |
| WTU      |         |     |     |     | ×                   |               |      | ×         |       |          |
| IPAS     |         |     |     |     |                     |               |      | ×         |       |          |
| HPU      |         |     |     |     | ×                   |               |      | ×         |       |          |
| T-ORILUX |         |     |     |     |                     |               |      |           | ×     |          |
| SDU      |         |     | ×   |     |                     |               |      |           |       |          |
| NCU      |         |     | ×   |     |                     |               |      |           |       |          |
| IME      |         |     |     |     |                     |               |      |           |       | ×        |
| USST     |         |     |     |     |                     |               | ×    |           |       |          |

# Naming of new ASICs

## ■ Data Link:

- **FEDA**: Front-End Data Aggregator ASIC
- **FEDI**: Front-End Data Interface ASIC
- **OAT**: Optical Array Transceiver Module
  - ALDD: Array Laser Diode Driver ASIC
  - ATIA: Array Transimpedance Amplifier ASIC

## ■ Power:

- **PAL**: Power At Load

## ■ OTK ASIC:

- **LATRIC**: LGAD Timing and Readout Integrated Chip

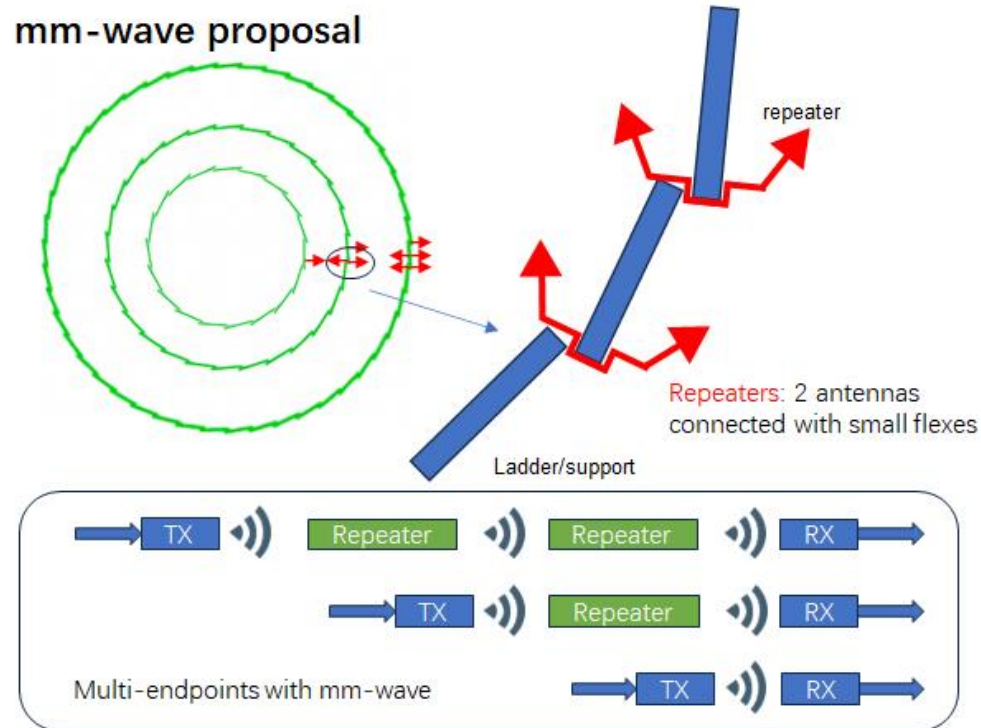
## ■ SiPM ASIC:

- **SIPAC**: SiPM ASIC for Calorimeter



# R&D efforts and results on WLess Comm

## mm-wave proposal

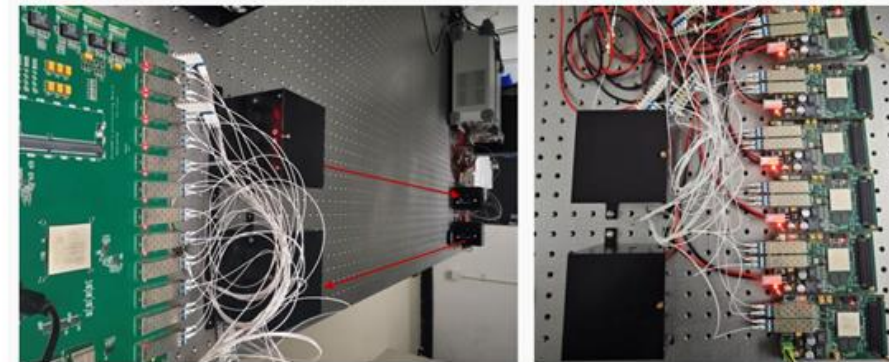
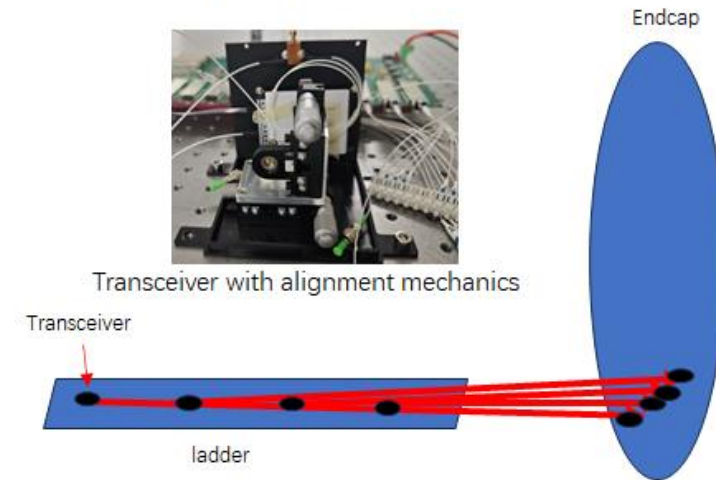


Test with evaluation boards – SK202

- Based on the commercial 60GHz RF chip ST60A2 transceiver from ST Microelectronics company.
- The transmission speed can exceed 900Mbps when the distance is less than 6 cm.

- Design a small PCB module with ST60A2, LNA and custom antenna.
- Higher bandwidth and longer distance
- Evaluate the interference with detector
- Under design, cheap and easy
- → custom transceiver + antenna + AIP

## Optical wireless proposal



DWDM transceivers + AWG + lens

- Up to 6-meter free space optical transmission distance
- 10Gbps X 12 channels bandwidth
- PRBS 31bits error rate < BER-15 @ 10Gbps under 1.6m distance

# A summary of FEE power

|                                      | Vertex                             | Pix(ITKB)                           | Strip (ITKE)                        | OTKB                   | OTKE | TPC                                             | ECAL-B                    | ECAL-E | HCAL-B | HCAL-E | Muon |
|--------------------------------------|------------------------------------|-------------------------------------|-------------------------------------|------------------------|------|-------------------------------------------------|---------------------------|--------|--------|--------|------|
| Channels per chip                    | 512*1024<br>Pixelized              | 512*128                             | 1024                                | 128                    |      | 128                                             | 8~16<br>@common SiPM ASIC |        |        |        |      |
| Technology                           | 65nm CIS                           | 55nm<br>HVCMOS                      | 55nm<br>HVCMOS                      | 55nm CMOS              |      | 65 CMOS                                         | 55nm CMOS (or 180 CMOS?)  |        |        |        |      |
| Power Supply Voltage (for DC-DC) (V) | 1.2                                | 1.2                                 | 1.2                                 | 1.2                    |      | 1.2                                             | 1.2 (or 1.8?)             |        |        |        |      |
| Power@chip                           | 40mW/cm <sup>2</sup><br>200mW/chip | 200mW/cm <sup>2</sup><br>800mW/chip | 200mW/cm <sup>2</sup><br>800mW/chip | 20mW/chn<br>2.56W/chip |      | 280μW/chn<br>35mW/chip<br>100mW/cm <sup>2</sup> | 15mW/chn<br>240mW/chip    |        |        |        |      |
| Max chips@module                     | 29                                 | 14                                  | 14                                  | 22                     | 22   | 1115                                            | 64                        | 120    | 8      | 92     | 167  |
| Power@module (W)                     | 5.8                                | 11.2                                | 11.2                                | 27.6                   | 27.6 | 32.2                                            | 30                        | 30     | 9      | 11     | 4.7  |